

LP5861 18 通道 LED 驱动器, 8 位模拟和 8 位/16 位 PWM 调光

1 特性

- 工作电压范围 :
 - V_{CC}/V_{LED} 范围 : 2.7V 至 5.5V
 - 逻辑引脚兼容 1.8V、3.3V 和 5V 电压
- 18 个高精度恒定电流阱 :
 - 当 $V_{CC} \geq 3.3V$ 时, 每个电流阱的电流为 0.1mA - 50mA
 - 器件间误差 : $\pm 5\%$
 - 通道间误差 : $\pm 5\%$
 - 相移可平衡瞬态功耗
- 超低功耗 :
 - 关断模式 : 当 EN 为低电平时 $I_{CC} \leq 2\mu A$
 - 待机模式 : 当 EN 为高电平且 CHIP_EN 为 0 (保留数据) 时 $I_{CC} \leq 10\mu A$
 - 工作模式 : 当通道电流为 5mA 时 $I_{CC} = 3mA$ (典型值)
- 灵活的调光选项 :
 - 对每个 LED 点进行单独的开关控制
 - 模拟调光 (电流增益控制)
 - 为所有 LED 点提供全局 3 位最大电流 (MC) 设置
 - 为红色、绿色和蓝色提供 3 组 7 位颜色电流 (CC) 设置
 - 为每个 LED 点提供单独的 8 位点电流 (DC) 设置
 - 以无可闻噪声的频率进行 PWM 调光
 - 为所有 LED 点实现全局 8 位 PWM 调光
 - 为 LED 点任意映射实现 3 组可编程 8 位 PWM 调光
 - 为每个 LED 点实现单独的 8 位或 16 位 PWM 调光
- 完整的可寻址 SRAM, 可更大限度地减少数据流量
- 针对各个 LED 点进行开路和短路检测
- 提供重影消除和低亮度补偿功能
- 接口选项 :
 - 当 IFS 为低电平时采用 1MHz (最大值) I²C 接口
 - 当 IFS 为高电平时采用 12MHz (最大值) SPI 接口

2 应用

- 用于以下设备的 LED 动画和指示 :
 - 键盘、鼠标和游戏附件
 - 大型和智能家用电器
 - 智能音箱、有线和无线音箱
 - 混音器、DJ 设备和广播
 - 接入设备、交换机和服务器

- 用于光学模块的恒定电流阱

3 说明

电子设备变得越来越智能, 而且需要使用更多的 LED 提供动画效果和指示功能, 因此需要使用高性能 LED 矩阵驱动器以小尺寸解决方案改善用户体验。

LP586x 器件是高性能 LED 矩阵驱动器系列。该系列器件集成了 18 个具有 N (N = 1/2/4/6/8/11) 个开关 MOSFET 的恒定电流阱, 以支持 N × 18 个 LED 点或 N × 6 个 RGB LED。LP5861 集成了 1 个 MOSFET, 从而支持多达 18 个 LED 点或 6 个 RGB LED。

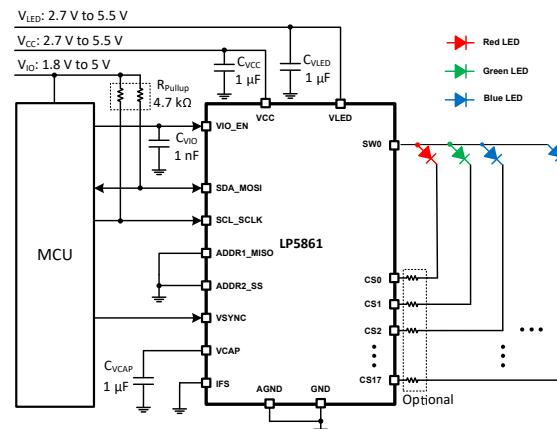
LP5861 同时支持模拟调光和 PWM 调光方法。对于模拟调光, 能够以 256 个阶跃来调节每个 LED 点。对于 PWM 调光, 集成式 8 位或 16 位可配置 PWM 发生器可实现平滑且无可闻噪声的调光控制。也可以将每个 LED 点任意映射到 8 位组 PWM, 以实现共同调光控制。

LP5861 器件实现了完整的可寻址 SRAM, 从而更大程度减少数据流量。集成了重影消除电路以消除上下重影。LP5861 还支持 LED 开路和短路检测功能。LP5861 同时支持 1MHz (最大值) I²C 和 12MHz (最大值) SPI。

器件信息

器件型号	封装 ⁽¹⁾	封装尺寸 (标称值)
LP5861	VQFN (32)	4mm × 4mm

- (1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。



简化版原理图



本文档旨在为方便起见, 提供有关 TI 产品中文版本的信息, 以确认产品的概要。有关适用的官方英文版本的最新信息, 请访问 www.ti.com, 其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前, 请务必参考最新版本的英文版本。

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

DATE	REVISION	NOTES
January 2022	*	Initial release

5 Device Comparison

PART NUMBER	MATERIAL	LED DOT NUMBER	PACKAGE ⁽²⁾	SOFTWARE COMPATIBLE	
LP5861	LP5861RSMR	18 × 1 = 18	VQFN-32	Yes	
LP5862	LP5862RSMR	18 × 2 = 36	VQFN-32		
	LP5862DBTR		TSSOP-38		
LP5864	LP5864RSMR	18 × 4 = 72	VQFN-32		
	LP5864MRSMR ⁽¹⁾				
LP5866	LP5866RKPR	18 × 6 = 108	VQFN-40		
	LP5866DBTR		TSSOP-38		
	LP5866MDBTR ⁽¹⁾				
LP5868	LP5868RKPR	18 × 8 = 144	VQFN-40		
LP5860	LP5861RKPR	18 × 11 = 198	VQFN-40		
	LP5861MRKPR ⁽¹⁾				

(1) Extended Temperature devices, supporting –55°C to approximately 125°C operating ambient temperature.

(2) The same packages are hardware compatible.

6 Pin Configuration and Functions

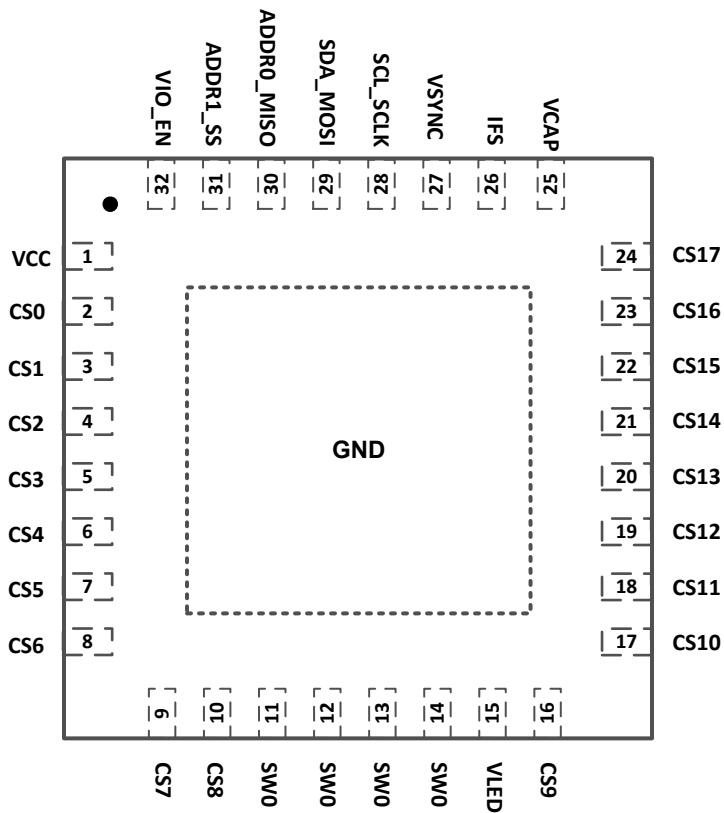


图 6-1. LP5861 RSM Package 32-Pin VQFN with Exposed Thermal Pad Top View

表 6-1. Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	VCC	Power	Power supply for device. A 1- μ F capacitor must be connected between this pin with GND and be placed as close to the device as possible.
2	CS0	O	Current sink 0. If not used, this pin must be left floating.
3	CS1	O	Current sink 1. If not used, this pin must be left floating.
4	CS2	O	Current sink 2. If not used, this pin must be left floating.
5	CS3	O	Current sink 3. If not used, this pin must be left floating.
6	CS4	O	Current sink 4. If not used, this pin must be left floating.
7	CS5	O	Current sink 5. If not used, this pin must be left floating.
8	CS6	O	Current sink 6. If not used, this pin must be left floating.
9	CS7	O	Current sink 7. If not used, this pin must be left floating.
10	CS8	O	Current sink 8. If not used, this pin must be left floating.
11/12/13/14	SW0	O	High-side PMOS switch output. All four pins must be tied together. If not used, this pin must be left floating.
15	VLED	Power	Power input for high-side switches.
16	CS9	O	Current sink 9. If not used, this pin must be left floating.
17	CS10	O	Current sink 10. If not used, this pin must be left floating.
18	CS11	O	Current sink 11. If not used, this pin must be left floating.
19	CS12	O	Current sink 12. If not used, this pin must be left floating.
20	CS13	O	Current sink 13. If not used, this pin must be left floating.

表 6-1. Pin Functions (continued)

PIN		I/O	DESCRIPTION
NO.	NAME		
21	CS14	O	Current sink 14. If not used, this pin must be left floating.
22	CS15	O	Current sink 15. If not used, this pin must be left floating.
23	CS16	O	Current sink 16. If not used, this pin must be left floating.
24	CS17	O	Current sink 17. If not used, this pin must be left floating.
25	VCAP	O	Internal LDO output. A 1- μ F capacitor must be connected between this pin with GND. Place the capacitor as close to the device as possible.
26	IFS	I	Interface type select. I ² C is selected when IFS is low. SPI is selected when IFS is high. A resistor must be connected between VIO and this pin.
27	VSYNC	I	External synchronize signal for display mode 2 and mode 3.
28	SCL_SCLK	I	I ² C clock input or SPI clock input. Pull up to VIO when configured as I ² C.
29	SDA_MOSI	I/O	I ² C data input or SPI leader output follower input. Pull up to VIO when configured as I ² C.
30	ADDR0_MISO	I/O	I ² C address select 0 or SPI leader input follower output
31	ADDR1_SS	I	I ² C address select 1 or SPI follower select
32	VIO_EN	Power,I	Power supply for digital circuits and chip enable. A 1-nF capacitor must be connected between this pin with GND and be placed as close to the device as possible.
Exposed Thermal Pad	GND	Ground	Common ground plane

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage on V_{CC} / V_{LED} / V_{IO} / EN / CS / SW / SDA / SCL / SCLK / MOSI / MISO / SS / ADDR0 / ADDR1 / VSYNC / IFS		- 0.3	6	V
Voltage on VCAP		- 0.3	2	V
T_J	Junction temperature	- 55	150	°C
T_{stg}	Storage temperature	- 65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±3000
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins ⁽²⁾	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Input voltage on V_{CC}	Supply voltage	2.7	5.5	V	
Input voltage on V_{LED}	LED supply voltage	2.7	5.5	V	
Input voltage on V_{IO_EN}		1.65	5.5	V	
Voltage on SDA / SCL / SCLK / MOSI / MISO / SS / ADDR _x / VSYNC / IFS				VIO	V
T_A	Operating ambient temperature	- 40	85	°C	
T_A	Operating ambient temperature - LP5860MRKPR, LP5864MRSR, and LP5866MDBTR only	- 55	125	°C	

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LP5864, LP5862, LP5861	UNIT
		RSM (VQFN)	
		32 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	32.9	°C/W
$R_{\theta JC(\text{top})}$	Junction-to-case (top) thermal resistance	29.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	12.3	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	0.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	12.3	°C/W
$R_{\theta JC(\text{bot})}$	Junction-to-case (bottom) thermal resistance	3.7	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

$V_{CC} = 3.3V$, $V_{LED} = 3.8V$, $V_{IO} = 1.8V$ and $T_A = -40^\circ C$ to $+85^\circ C$ ($T_A = -55^\circ C$ to $+125^\circ C$ for LP5860MRKPR, LP5864MRSMR, and LP5866MDBTR); Typical values are at $T_A = 25^\circ C$ (unless otherwise specified)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power supplies					
V_{CC}	Device supply voltage	2.7	5.5		V
V_{UVR}	Undervoltage restart		2.5		V
V_{UVF}	Undervoltage shutdown	1.9			V
V_{UV_HYS}	Undervoltage shutdown hysteresis		0.3		V
V_{CAP}	Internal LDO output	1.78			V
I_{CC}	Shutdown supply current $I_{SHUTDOWN}$	0.1	1		μA
	Standby supply current $I_{STANDBY}$	5.5	10		μA
	Active mode supply current I_{NORMAL}	4.3	6		mA
V_{LED}	LED supply voltage	2.7	5.5		V
V_{VIO}	VIO supply voltage	1.65	5.5		V
I_{VIO}	VIO supply current		5		μA
Output Stages					
I_{CS}	Constant current sink output range (CS0 - CS17)	2.7 V $\leq V_{CC} < 3.3$ V, PWM = 100%	0.1	40	mA
		$V_{CC} \geq 3.3$ V PWM = 100%	0.1	50	mA
I_{LKG}	Leakage current (CS0 - CS17)	channels off, up_deghost = 0, $V_{CS}=5V$	0.1	1	μA
I_{ERR_DD}	Device to device current error, $I_{ERR_DD} = (I_{AVE} - I_{SET}) / I_{SET} \times 100\%$	All channels ON. Current set to 0.1 mA. MC = 0 CC = 42 DC = 25 PWM = 100%	- 7	7	%
		All channels ON. Current set to 1 mA. MC = 2 CC = 127 DC = 25 PWM = 100%	- 5	5	%
		All channels ON. Current set to 10 mA. MC = 2 CC = 127 DC = 255 PWM = 100%	- 3.5	3.5	%
		All channels ON. Current set to 25 mA. MC = 7 CC = 64 DC = 255 PWM = 100%	- 3.5	3.5	%
		All channels ON. Current set to 50 mA. MC = 7 CC = 127 DC = 255 PWM = 100%	- 3	3	%
I_{ERR_CC}	Channel to channel current error, $I_{ERR_CC} = (I_{OUTX} - I_{AVE}) / I_{AVE} \times 100\%$	All channels ON. Current set to 0.1 mA. MC = 0 CC = 42 DC = 25 PWM = 100%	- 5.5	5.5	%
		All channels ON. Current set to 1 mA. MC = 2 CC = 127 DC = 25 PWM = 100%	- 5	5	%
		All channels ON. Current set to 10 mA. MC = 2 CC = 127 DC = 255 PWM = 100%	- 4	4	%
		All channels ON. Current set to 25 mA. MC = 7 CC = 64 DC = 255 PWM = 100%	- 3.5	3.5	%
		All channels ON. Current set to 50 mA. MC = 7 CC = 127 DC = 255 PWM = 100%	- 3	3	%
f_{PWM}	LED PWM frequency	PWM_Fre = 1, PWM = 100%	62.5		KHz
		PWM_Fre = 0, PWM = 100%	125		KHz

7.5 Electrical Characteristics (continued)

$V_{CC} = 3.3V$, $V_{LED} = 3.8V$, $V_{IO} = 1.8V$ and $T_A = -40^\circ C$ to $+85^\circ C$ ($T_A = -55^\circ C$ to $+125^\circ C$ for LP5860MRKPR, LP5864MRSR, and LP5866MDBTR); Typical values are at $T_A = 25^\circ C$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{SAT}	Output saturation voltage	$I_{OUT} = 50 \text{ mA}$, decreasing output voltage, when the LED current has dropped 5%			0.45	V
		$I_{OUT} = 30 \text{ mA}$, decreasing output voltage, when the LED current has dropped 5%			0.4	V
		$I_{OUT} = 10 \text{ mA}$, decreasing output voltage, when the LED current has dropped 5%			0.35	V
R_{SW}	High-side PMOS ON resistance	$V_{LED} = 2.7 \text{ V}$, $I_{SW} = 200 \text{ mA}$		450	550	$\text{m}\Omega$
		$V_{LED} = 3.8 \text{ V}$, $I_{SW} = 200 \text{ mA}$		380	500	$\text{m}\Omega$
		$V_{LED} = 5 \text{ V}$, $I_{SW} = 200 \text{ mA}$		310	450	$\text{m}\Omega$

Logic Interfaces

V_{LOGIC_IL}	Low-level input voltage, SDA, SCL, SCLK, MOSI, SS, ADDR _x , VSYNC, IFS		0.3 x V_{IO}	V	
V_{LOGIC_IH}	High-level input voltage, SDA, SCL, SCLK, MOSI, SS, ADDR _x , VSYNC, IFS		0.7 x V_{IO}	V	
V_{EN_IL}	Low-level input voltage of EN		0.4	V	
V_{EN_IH}	High-level input voltage of EN	When V_{CAP} powered up	1.4	V	
I_{LOGIC_I}	Input current, SDA, SCL, SCLK, MOSI, SS, ADDR _x		-1	1	μA
$V_{LOGIC_O_L}$	Low-level output voltage, SDA, MISO	$I_{PULLUP} = 3 \text{ mA}$		0.4	V
$V_{LOGIC_O_H}$	High-level output voltage, MISO	$I_{PULLUP} = -3 \text{ mA}$	0.7 x V_{IO}	V	

Protection Circuits

V_{LOD_TH}	Thershold for channel open detection		0.25	V
V_{LSD_TH}	Thershold for channel short detection		$V_{LED} - 1$	V
T_{TSD}	Thermal-shutdown junction temperature		150	$^\circ\text{C}$
T_{HYS}	Thermal shutdown temperature hysteresis		15	$^\circ\text{C}$

7.6 Timing Requirements

		MIN	NOM	MAX	UNIT
MISC. Timing Requirements					
f_{OSC}	Internal oscillator frequency		31.2		MHz
f_{OSC_ERR}	Device to device oscillator frequency error	-3%	3%		
t_{POR_H}	Wait time from UVLO disactive to device NORMAL		500		μs
t_{CHIP_EN}	Wait time from setting Chip_EN (Register) =1 to device NORMAL		100		μs
t_{RISE}	LED output rise time		10		ns
t_{FALL}	LED output fall time		15		ns
t_{VSYNC_H}	The minimum high-level pulse width of VSYNC	200			μs
SPI timing requirements					
f_{SCLK}	SPI Clock frequency			12	MHz
1	Cycle time	83.3			ns
2	SS active lead-time	50			ns
3	SS active leg time	50			ns
4	SS inactive time	50			ns
5	SCLK low time	36			ns
6	SCLK high time	36			ns
7	MOSI set-up time	20			ns

7.6 Timing Requirements (continued)

		MIN	NOM	MAX	UNIT
8	MOSI hold time	20			ns
9	MISO disable time			30	ns
10	MISO data valid time			35	ns
C _b	Bus capacitance	5	40		pF
I²C fast mode timing requirements					
f _{SCL}	I ² C clock frequency	0	400		KHz
1	Hold time (repeated) START condition	600			ns
2	Clock low time	1300			ns
3	Clock high time	600			ns
4	Set-up time for a repeated START condition	600			ns
5	Data hold time	0			ns
6	Data set-up time	100			ns
7	Rise time of SDA and SCL			300	ns
8	Fall time of SDA and SCL			300	ns
9	Set-up time for STOP condition	600			ns
10	Bus free time between a STOP and a START condition	1.3			μs
I²C fast mode plus timing requirements					
f _{SCL}	I ² C clock frequency	0	400		KHz
1	Hold time (repeated) START condition	600			ns
2	Clock low time	1300			ns
3	Clock high time	600			ns
4	Setup time for a repeated START condition	600			ns
5	Data hold time	0			ns
6	Data setup time	100			ns
7	Rise time of SDA and SCL			300	ns
8	Fall time of SDA and SCL			300	ns
9	Set-up time for STOP condition	600			ns
10	Bus free time between a STOP and a START condition	1.3			μs

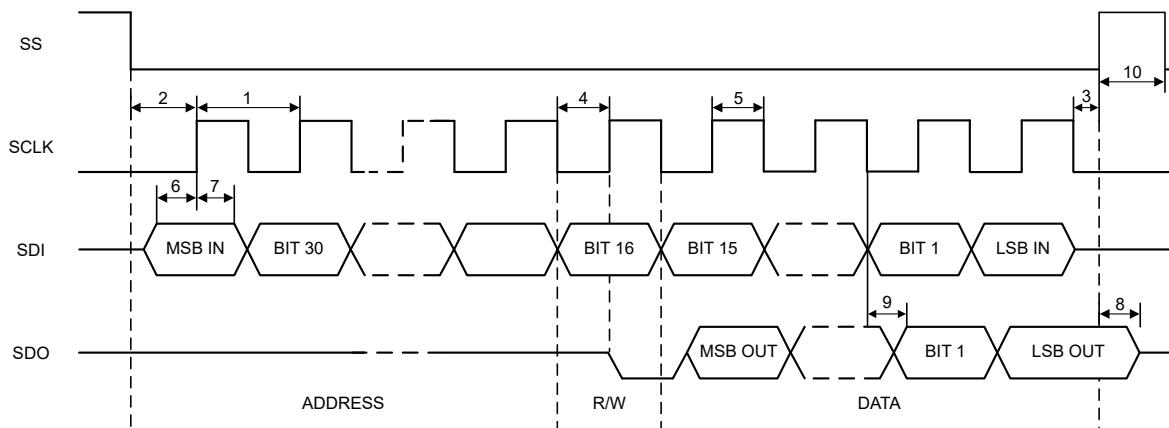


图 7-1. SPI Timing Parameters

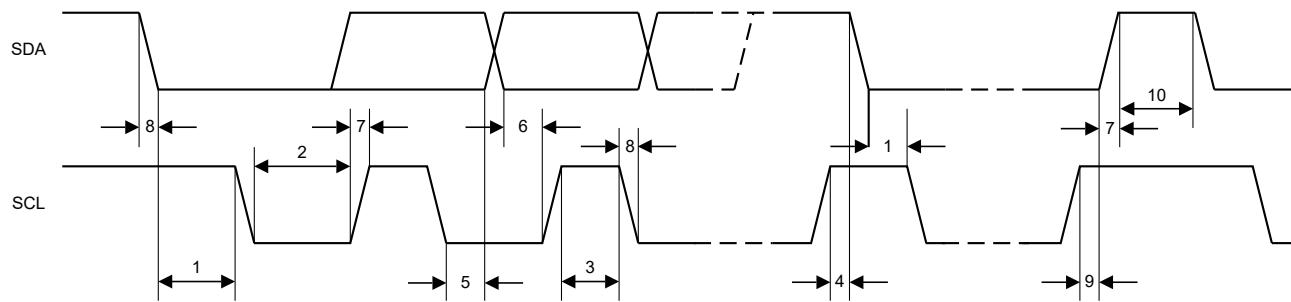


图 7-2. I²C Timing Parameters

7.7 Typical Characteristics

Unless specified otherwise, typical characteristics apply over the full ambient temperature range ($-55^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$ for LP5860MRKPR, LP5864MRSR, and LP5866MDBTR while $-40^{\circ}\text{C} < T_A < +85^{\circ}\text{C}$ for the other devices), $V_{\text{CC}} = 3.3\text{ V}$, $V_{\text{IO}} = 3.3\text{ V}$, $V_{\text{LED}} = 5\text{ V}$, $I_{\text{LED Peak}} = 50\text{ mA}$, $C_{\text{VLED}} = 1\text{ }\mu\text{F}$, $C_{\text{VCC}} = 1\text{ }\mu\text{F}$.

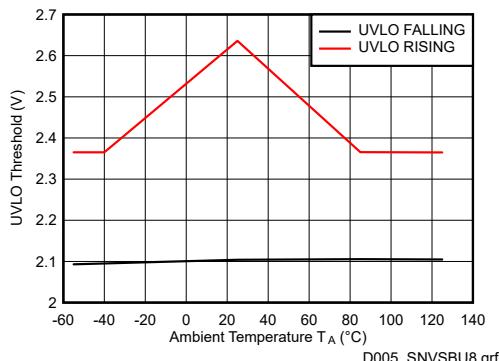


图 7-3. V_{CC} UVLO Rising and Falling Thresholds

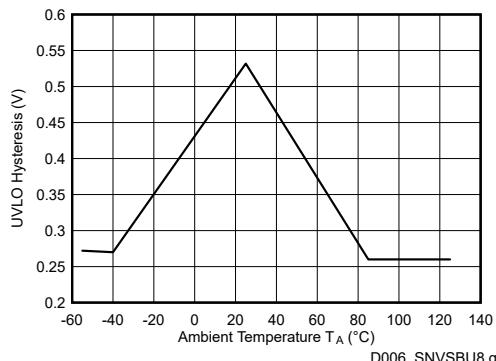


图 7-4. V_{CC} UVLO Hysteresis

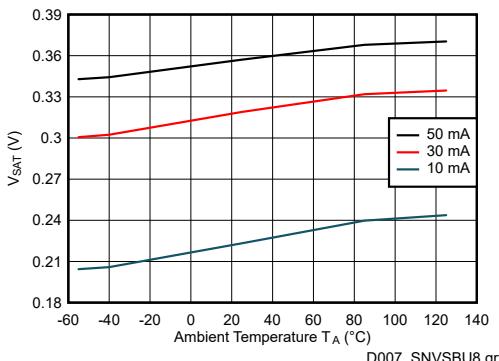


图 7-5. V_{SAT} vs Temperature

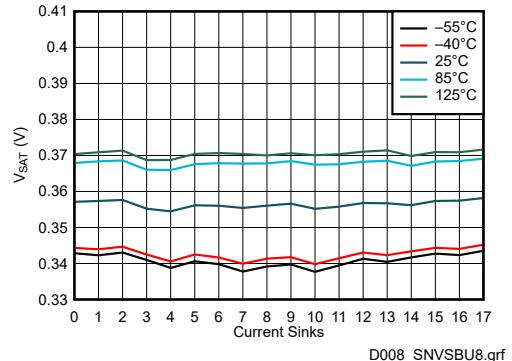


图 7-6. V_{SAT} vs Current Sinks (50 mA)

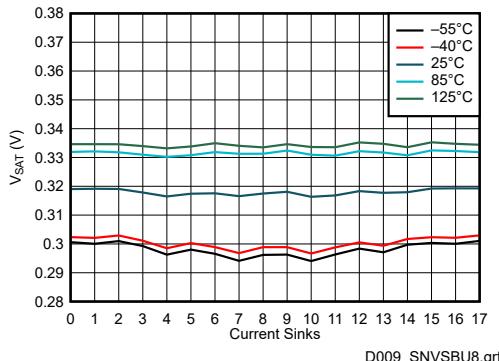


图 7-7. V_{SAT} vs Current Sinks (30 mA)

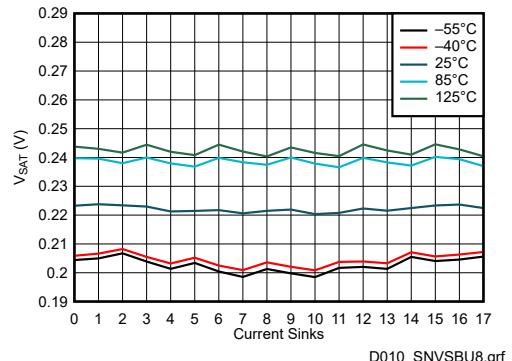
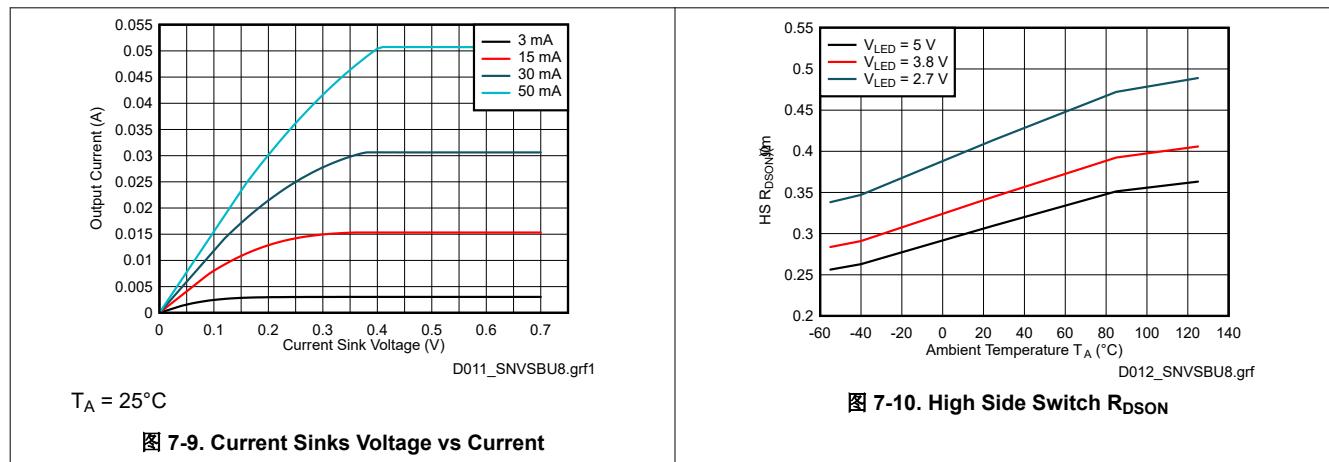


图 7-8. V_{SAT} vs Current Sinks (10 mA)

7.7 Typical Characteristics (continued)

Unless specified otherwise, typical characteristics apply over the full ambient temperature range ($-55^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$ for LP5860MRKPR, LP5864MRSMR, and LP5866MDBTR while $-40^{\circ}\text{C} < T_A < +85^{\circ}\text{C}$ for the other devices), $V_{\text{CC}} = 3.3\text{ V}$, $V_{\text{IO}} = 3.3\text{ V}$, $V_{\text{LED}} = 5\text{ V}$, $I_{\text{LED_Peak}} = 50\text{ mA}$, $C_{\text{VLED}} = 1\text{ }\mu\text{F}$, $C_{\text{VCC}} = 1\text{ }\mu\text{F}$.



8 Detailed Description

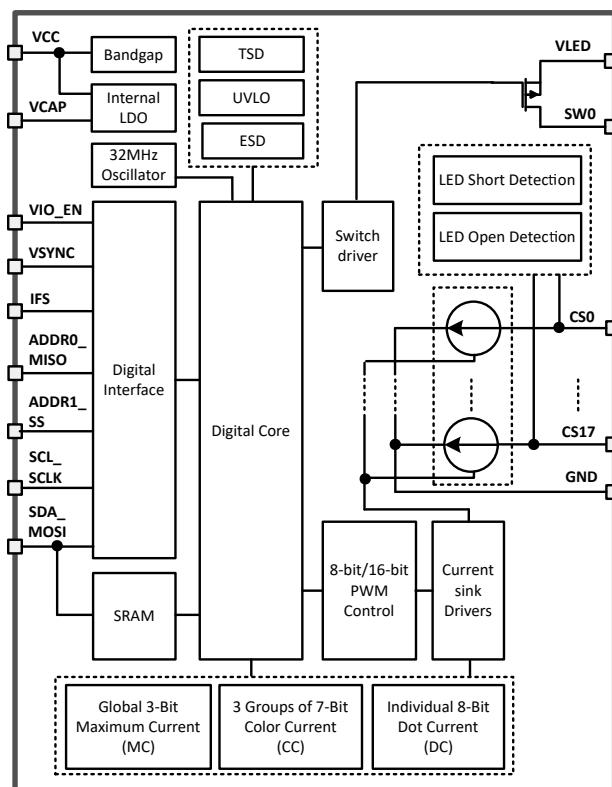
8.1 Overview

The LP5861 is an 18 channels LED driver. The device integrates 18 high-precision constant-current sinks. One LP5861 device can drive up to 18 LED dots or 6 RGB pixels by directly driving the LEDs.

The LP5861 supports both analog dimming and PWM dimming methods. For analog dimming, the current gain of each individual LED dot can be adjusted with 256 steps through 8-bits dot correction. For PWM dimming, the integrated 8-bits or 16-bits configurable, > 20-KHz PWM generators for each LED dot enable smooth, vivid animation effects without audible noise. Each LED can also be mapped into a 8-bits group PWM to achieve the group control with minimum data traffic.

The LP5861 device implements full addressable SRAM. The device supports entire SRAM data refresh and partial SRAM data update on demand to minimize the data traffic. The LP5861 implements the ghost cancellation circuit to eliminate both upside and downside ghosting. The LP5861 also uses low brightness compensation technology to support high density LED pixels. Both 1-MHz (maximum) I²C and 12-MHz (maximum) SPI interfaces are available in the LP5861.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Analog Dimming (Current Gain Control)

Analog dimming of LP5861 is achieved by configuring the current gain control. There are several methods to control the current gain of each LED.

- Global 3-bits Maximum Current (MC) setting without external resistor
- 3 Groups of 7-bits Color Current (CC) setting
- Individual 8-bit Dot Current (DC) setting

Global 3-Bits Maximum Current (MC) Setting

The MC is used to set the maximum current I_{OUT_MAX} for each current sink and this current is the maximum peak current for each LED dot. The MC can be set with 3-bits (8 steps) from 3 mA to 50 mA. When the device is powered on, the MC data is set to default value, which is 15 mA.

For data refresh **Mode 1**, MC data is effective immediately after new data updated. For **Mode 2** and **Mode 3**, to avoid unexpected MC data change during high speed data refreshing, MC data must be changed when all channels are off and new MC data is only be updated when the 'Chip_EN' bit in Chip_en register is set to 0, and after the 'Chip_EN' returns to 1, the new MC data is effective. 'Down_Deghost' and 'Up_Deghost' in Dev_config3 work in the similar way with MC.

表 8-1. Maximum Current (MC) Register Setting

3-BITS MAXIMUM_CURRENT REGISTER		I_{OUT_MAX}
Binary	Decimal	mA
000	0	3
001	1	5
010	2	10
011 (default)	3 (default)	15 (default)
100	4	20
101	5	30
110	6	40
111	7	50

3 Groups of 7-Bits Color Current (CC) Setting

The LP5861 device is able to adjust the output current of three color groups separately. For each color, the device has 7-bits data in 'CC_Group1', 'CC_Group2', and 'CC_Group3'. Thus, all color group currents can be adjusted in 128 steps from 0% to 100% of the maximum output current, I_{OUT_MAX} .

The 18 current sinks have fixed mapping to the three color groups:

- CC-Group 1: CS0, CS3, CS6, CS9, CS12, CS15
- CC-Group 2: CS1, CS4, CS7, CS10, CS13, CS16
- CC-Group 3: CS2, CS5, CS8, CS11, CS14, CS17

表 8-2. 3 Groups of 7-bits Color Current (CC) Setting

7-BITS CC_GROUP1/CC_GROUP2/CC_GROUP3 REGISTER		RATIO OF OUTPUT CURRENT TO I_{OUT_MAX}
Binary	Decimal	%
000 0000	0	0
000 0001	1	0.79
000 0010	2	1.57
---	---	---
100 0000 (default)	64 (default)	50.4 (default)
---	---	---
111 1101	125	98.4
111 1110	126	99.2
111 1111	127	100

Individual 8-bit Dot Current (DC) Setting

The LP5861 can individually adjust the output current of each LED by using dot current function through DC setting. The device allows the brightness deviations of the LEDs to be adjusted individually. Each output DC is programmed with a 8-bit depth, so the value can be adjusted with 256 steps within the range from 0% to 100% of ($I_{OUT_MAX} \times CC/127$).

表 8-3. Individual 8-bit Dot Current (DC) Setting

8-BIT DC REGISTER		RATIO OF OUTPUT CURRENT TO $I_{OUT_MAX} \times CC/127$
Binary	Decimal	%
0000 0000	0	0
0000 0001	1	0.39
0000 0010	2	0.78
---	---	---
1000 0000 (default)	128 (default)	50.2 (default)
---	---	---
1111 1101	253	99.2
1111 1110	254	99.6
1111 1111	255	100

In summary, the current gain of each current sink can be calculated as below:

$$I_{OUT} (\text{mA}) = I_{OUT_MAX} \times (CC/127) \times (DC/255) \quad (1)$$

8.3.2 PWM Dimming

There are several methods to control the PWM duty cycle of each LED dot.

- **Individual 8-bit / 16-bit PWM for Each LED Dot**

Every LED has an individual 8-bit or 16-bit PWM register that is used to change the LED brightness by PWM duty. The LP5861 uses an enhanced spectrum PWM (ES-PWM) algorithm to achieve 16-bit depth with high refresh rate and this can avoid flicker under high speed camera. Comparing with conventional 8-bit PWM, 16-bit PWM can help to achieve ultimate high dimming resolution in LED animation applications.

- **3 Programmable Groups of 8-bit PWM Dimming**

The group PWM Control is used to select LEDs into one to three groups where each group has a separate register for duty cycle control. Every LED has 2-bit selection in LED_DOT_GROUP Registers ($x = 0, 1, \dots, 4$) to select whether it belongs to one of the three groups or not:

- 00: not a member of any group
- 01: member of group 1
- 10: member of group 2
- 11: member of group 3

- **8-bit PWM for Global Dimming**

The Global PWM Control function affects all LEDs simultaneously.

The final PWM duty cycle can be calculated as below:

$$PWM_{Final}(8 \text{ bit}) = PWM_{Individual}(8 \text{ bit}) \times PWM_{Group}(8 \text{ bit}) \times PWM_{Global}(8 \text{ bit}) \quad (2)$$

$$PWM_{Final}(16 \text{ bit}) = PWM_{Individual}(16 \text{ bit}) \times PWM_{Group}(8 \text{ bit}) \times PWM_{Global}(8 \text{ bit}) \quad (3)$$

The LP5861 supports 125-kHz or 62.5-kHz PWM output frequency. The PWM frequency is selected by configuring the 'PWM_Fre' in Dev_initial register. An internal 32-MHz oscillator is used for generating PWM outputs. The oscillator's high accuracy design ($f_{OSC_ERR} \leq \pm 2\%$) enables a better synchronization if multiple LP5861 devices are connected together.

A PWM phase-shifting scheme is implemented in each current sink to avoid the current overshoot when turning on simultaneously. As the LED drivers are not activated simultaneously, the peak load current from the pre-stage power supply is significantly decreased. This scheme also reduces input-current ripple and ceramic-capacitor

audible ringing. LED drivers are grouped into three different phases. By configuring the 'PWM_Phase_Shift' in Dev_config1 register, which is default off, the LP5861 supports $t_{phase_shift} = 125\text{-ns}$ shifting time shown in [图 8-1](#).

- Phase 1: CS0, CS3, CS6, CS9, CS12, CS15
- Phase 2: CS1, CS4, CS7, CS10, CS13, CS16
- Phase 3: CS2, CS5, CS8, CS11, CS14, CS17

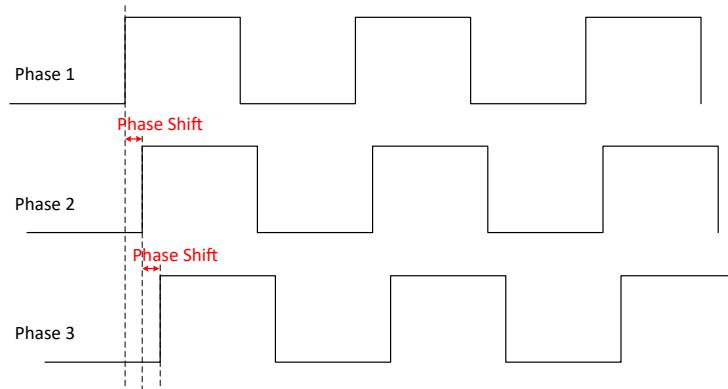


图 8-1. Phase Shift

- **Low Brightness Compensation:** three groups compensation are implemented to overcome the color-shift and non-uniformity in low brightness conditions. The compensation capability can be through 'Comp_Group1', 'Comp_Group2', and 'Comp_Group3' in Dev_config2 register.
 - Compensation_group 1: CS0, CS3, CS6, CS9, CS12, CS15
 - Compensation_group 2: CS1, CS4, CS7, CS10, CS13, CS16
 - Compensation_group 3: CS2, CS5, CS8, CS11, CS14, CS17

The LP5861 allows users to configure the dimming scale either exponentially (Gamma Correction) or linearly through the 'PWM_Scale_Mode' in Dev_config1 register. If a human-eye-friendly dimming curve is desired, using the internal fixed exponential scale is an easy approach. If a special dimming curve is desired, using the linear scale with software correction is recommended. The LP5861 supports both linear and exponential dimming curves under 8-bit and 16-bit PWM depth. [图 8-2](#) is an example of 8-bit PWM depth.

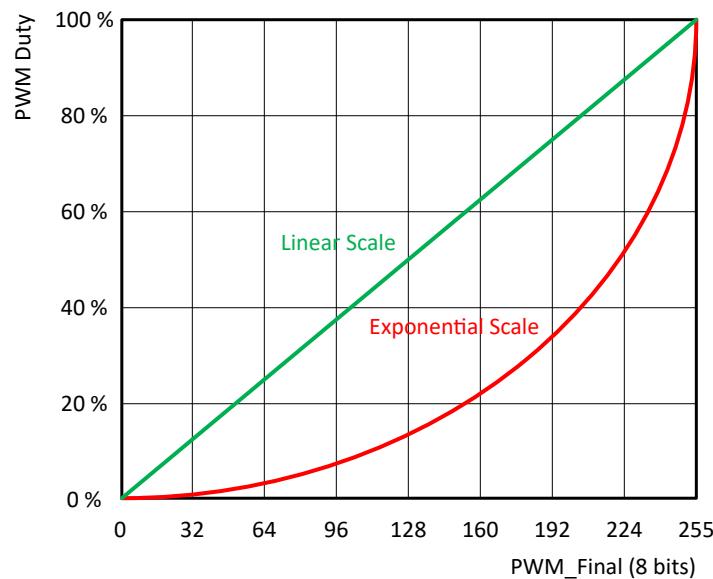


图 8-2. Linear and Exponential Dimming Curves

In summary, the PWM control method is illustrated as [图 8-3](#):

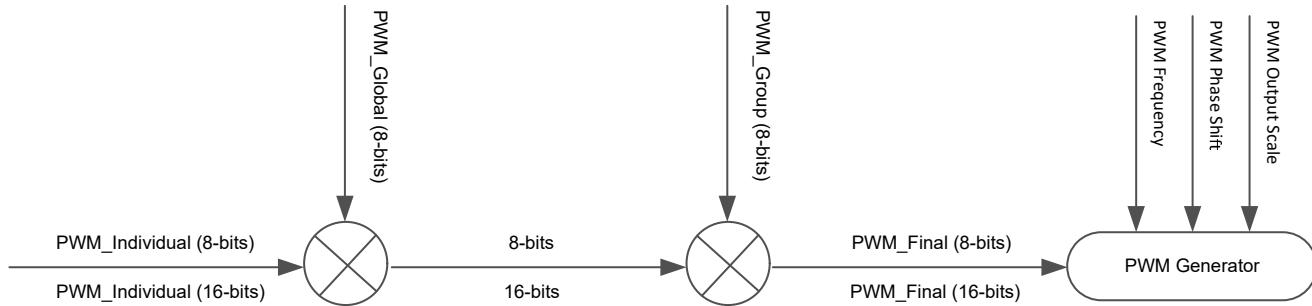


图 8-3. PWM Control Scheme

8.3.3 ON and OFF Control

The LP5861 device supports the individual ON and OFF control of each LED. For indication purpose, users can turn on and off the LED directly by writing 1-bit ON and OFF data to the corresponding Dot_onoffx ($x = 0, 1, \dots, 2$) register.

8.3.4 Data Refresh Mode

The LP5861 supports three data refresh modes: Mode 1, Mode 2, and Mode 3, by configuring 'Data_Ref_Mode' in Dev_initial register.

Mode 1: 8-bit PWM data without VSYNC command. Data is sent out for display instantly after received. With Mode 1, users can refresh the corresponding dots' data only instead of updating the whole SRAM. It is called 'on demand data refresh', which can save the total data volume effectively. As shown in [图 8-4](#), the red LED dots can be refreshed after sending the corresponding data while the others kept the same with last frame.

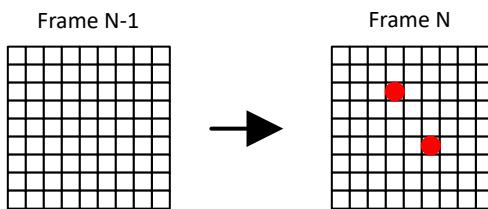


图 8-4. On Demand Data Refresh - Mode 1

Mode 2: 8-bit PWM data with VSYNC command. Data is held and sent out simultaneously by frame after receiving the VSYNC command.

Mode 3: 16-bit PWM data with VSYNC command. Data is held and sent out simultaneously by frame after receiving the VSYNC command.

Frame control is implemented in Mode 2 and Mode 3. Instead of refreshing the output instantly after data is received (Mode 1), the device holds the data and refreshes the whole frame data by a fixed frame rate, f_{VSYNC} . Usually, 24 Hz, 50 Hz, 60 Hz, 120 Hz or even higher frame rate is selected to achieve vivid animation effects. Whole SRAM Data Refresh is shown in [图 8-5](#), a new frame is updated after receiving the VSYNC command.

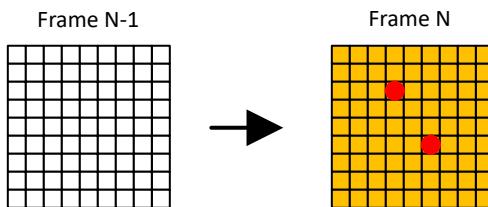


图 8-5. Whole SRAM Data Refresh

Comparing with Mode 1, Mode 2 and Mode 3 provide a better synchronization when multiple LP5861 devices used together. A high-level pulse width longer than t_{VSYNC_H} is required at the beginning of each VSYNC frame. [图 8-6](#) shows the VSYNC connections and [图 8-7](#) shows the timing requirements.

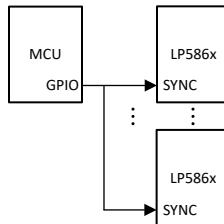


图 8-6. Multiple Devices Sync

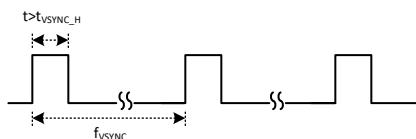


图 8-7. VSYNC Timing

[Table 8-4](#) is the summary of the three data refresh modes.

表 8-4. Data Refresh Mode

MODE TYPE	PWM RESOLUTION	PWM OUTPUT	EXTERNAL VSYNC
Mode 1	8 bits	Data update instantly	No
Mode 2	8 bits	Data update by frame	Yes
Mode 3	16 bits		

8.3.5 Full Addressable SRAM

SRAM is implemented inside the LP5861 device to support data writing and reading at the same time.

Although data refresh mechanisms are not the same for Mode 1 and Mode 2 and 3, the data writing and reading follow the same method. Users can update partial of the SRAM data only or the whole SRAM page simultaneously. The LP5861 supports auto-increment function to minimize data traffic and increase data transfer efficiency.

Please note that 16-bit PWM (Mode 3) and 8-bit PWM (Mode 1 and Mode 2) are assigned with different SRAM addresses.

8.3.6 Protections and Diagnostics

LED Open Detection

The LP5861 includes LED open detection (LOD) for the fault caused by any opened LED dot. The threshold for LED open is 0.25-V typical. LED open detection is only performed when $PWM \geq 25$ (Mode 1 and Mode 2) or $PWM \geq 6400$ (Mode 3) and voltage on CSn is detected lower than open threshold for continuously 4 sub-periods.

[图 8-8](#) shows the detection circuit of LOD function. When open fault is detected, 'Global_LOD' bit in Fault_state register is set to 1 and detailed fault state for each LED is also monitored in register Dot_lodx ($x = 0, 1, \dots, 2$). All open fault indicator bits can be cleared by setting LOD_clear = 0Fh after the open condition is removed.

LOD removal function can be enabled by setting 'LOD_removal' bit in Dev_config2 register to 1. This function turns off the current sink of the open channel when scanning to the line where the opened LED is included.

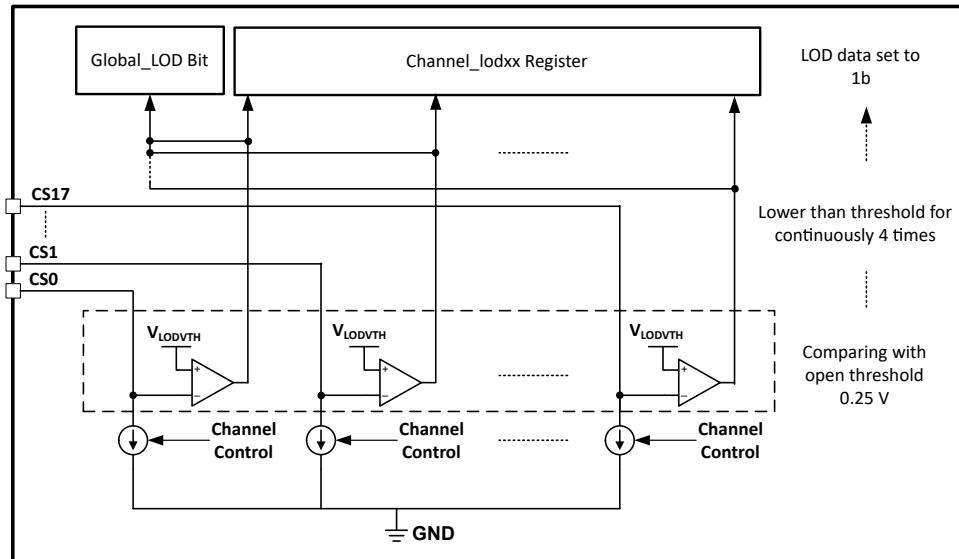


图 8-8. LOD Circuits

LED Short Detection

The LP5861 includes LED short detection (LSD) for the fault caused by any shorted LED. Threshold for channel short is $(V_{LED} - 1)$ V typical. LED short detection only performed when $PWM \geq 25$ (Mode 1 and Mode 2) or $PWM \geq 6400$ (Mode 3) and voltage on CSn is detected higher than short threshold for continuously 4 sub-periods. As there is parasitic capacitance for the current sink, to make sure the LSD result is correct, TI recommends to set the LED current higher than 0.5 mA.

图 8-9 shows the detection circuit of LSD function. When short fault is detected, 'Global_LSD bit' in Fault_state register is set to 1 and detailed fault state for every channel is also monitored in register Dot_lsdxx (x = 0, 1, ..., 2). All short fault indicator bits can be cleared by setting LSD_clear = 0Fh after the short condition is removed.

LSD removal function can be enabled by setting 'LSD_removal' bit in Dev_config2 register to 1. This function turns off the upside deghosting function of the scan line where short LED is included.

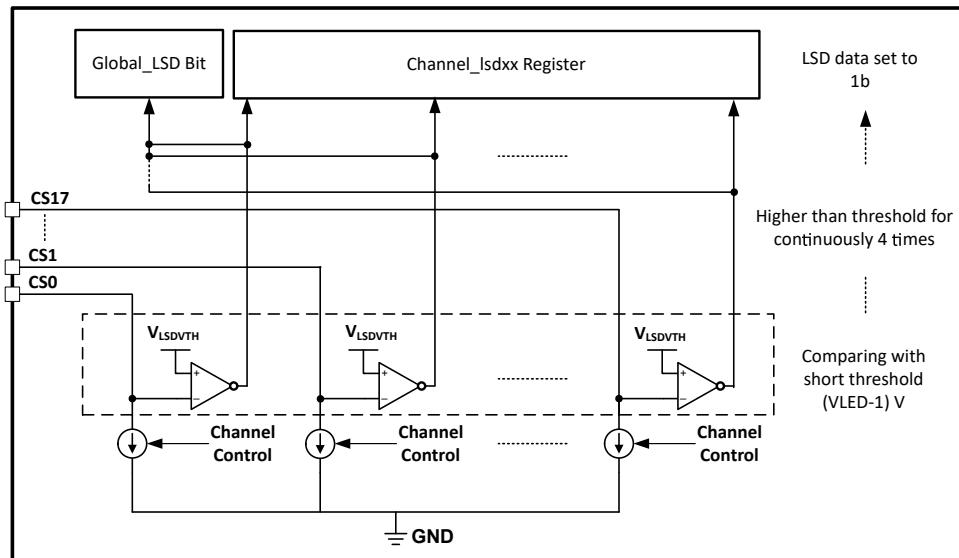


图 8-9. LSD Circuit

Thermal Shutdown

The LP5861 device implements thermal shutdown mechanism to protect the device from damage due to overheating. When the junction temperature rises to 160 °C (typical) and above, the device switches into shutdown mode. The LP5861 exits thermal shutdown when the junction temperature of the device drops to 145 °C (typical) and below.

UVLO (Undervoltage Lockout)

The LP5861 has an internal comparator that monitors the voltage at VCC. When VCC is below V_{UVF} , reset is active and the LP5861 enters INITIALIZATION state.

8.4 Device Functional Modes

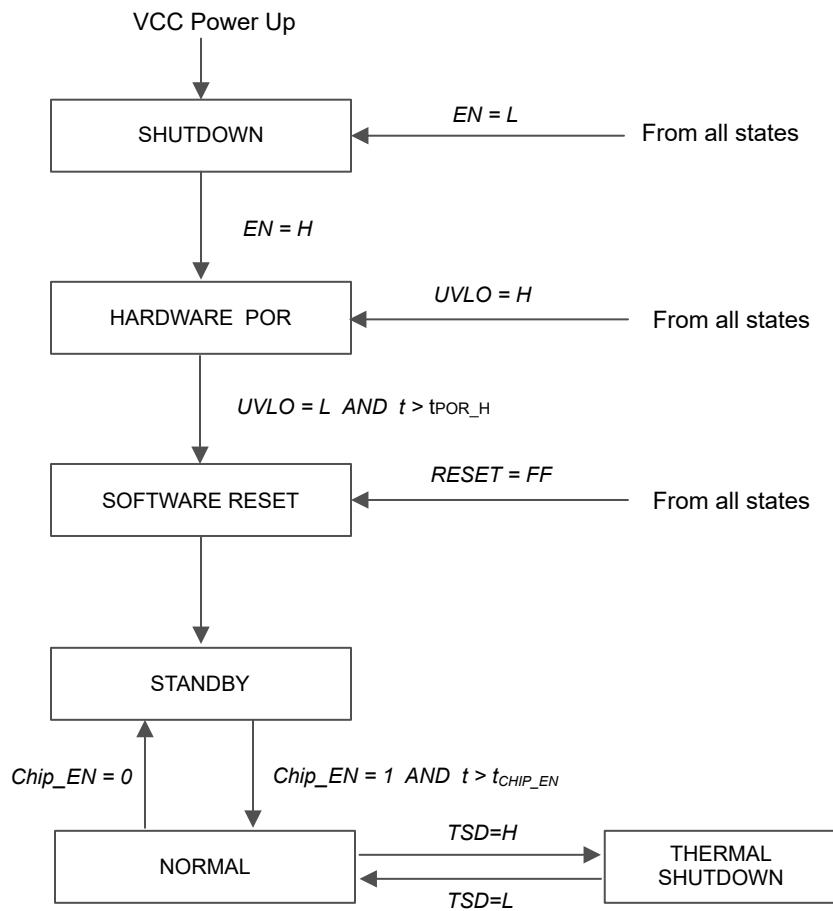


图 8-10. Device Functional Modes

- Shutdown: The device enters into shutdown mode from all states on VCC power up or EN pin is low.
- Hardware POR: The device enters into hardware POR when Enable pin is high or VCC fall under V_{UVF} causing UVLO = H from all states.
- Software reset: The device enters into software reset mode when VCC rise higher than V_{UVR} with the time $t > t_{POR_H}$. In this mode, all the registers are reset. Entry can also be from any state when the RESET (register) = FFh or UVLO is low.
- Standby: The device enters the standby mode when Chip_EN (register) = 0. In this mode, the device enters into low power mode, but the I²C/SPI are still available for Chip_EN only and the registers' data are retained.
- Normal: The device enters the normal mode when 'Chip_EN' = 1 with the time $t > t_{CHIP_EN}$.
- Thermal shutdown: The device automatically enters the thermal shutdown mode when the junction temperature exceeds 160°C (typical). If the junction temperature decreases below 145°C (typical), the device returns to the normal mode.

8.5 Programming

Interface Selection

The LP5861 supports two communication interfaces: I²C and SPI. If IFS is high, it enters into SPI mode. If IFS is low, it enters into I²C mode.

表 8-5. Interface Selection

INTERFACE TYPE	ENTRY CONDITION
I ² C	IFS = Low
SPI	IFS = High

I²C Interface

The LP5861 is compatible with I²C standard specification. The device supports both fast mode (400-KHz maximum) and fast plus mode (1-MHz maximum).

I²C Data Transactions

The data on SDA line must be stable during the HIGH period of the clock signal (SCL). In other words, state of the data line can only be changed when clock signal is LOW. START and STOP conditions classify the beginning and the end of the data transfer session. A START condition is defined as the SDA signal transitioning from HIGH to LOW while SCL line is HIGH. A STOP condition is defined as the SDA transitioning from LOW to HIGH while SCL is HIGH. The bus leader always generates START and STOP conditions. The bus is considered to be busy after a START condition and free after a STOP condition. During data transmission, the bus leader can generate repeated START conditions. First START and repeated START conditions are functionally equivalent.

Each byte of data has to be followed by an acknowledge bit. The acknowledge related clock pulse is generated by the leader. The leader releases the SDA line (HIGH) during the acknowledge clock pulse. The device pulls down the SDA line during the 9th clock pulse, signifying an acknowledge. The device generates an acknowledge after each byte has been received.

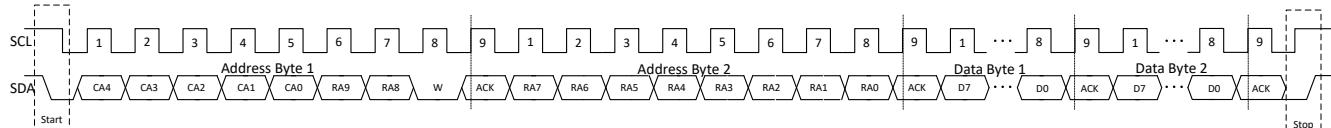
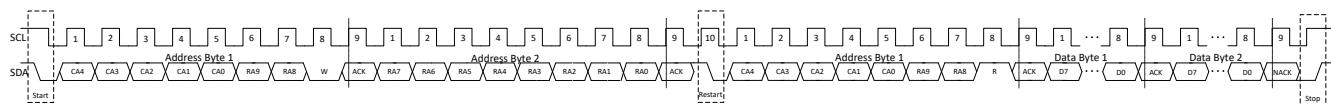
There is one exception to the acknowledge after every byte rule. When the leader is the receiver, it must indicate to the transmitter an end of data by not acknowledging (*negative acknowledge*) the last byte clocked out of the follower. This negative acknowledge still includes the acknowledge clock pulse (generated by the leader), but the SDA line is not pulled down.

I²C Data Format

The address and data bits are transmitted MSB first with 8-bits length format in each cycle. Each transmission is started with Address Byte 1, which are divided into 5-bits of the chip address, 2 higher bits of the register address, and 1 read and write bit. The other 8 lower bits of register address are put in Address Byte 2. The device supports both independent mode and broadcast mode. The auto-increment feature allows writing and reading several consecutive registers within one transmission. If not consecutive, a new transmission must be started.

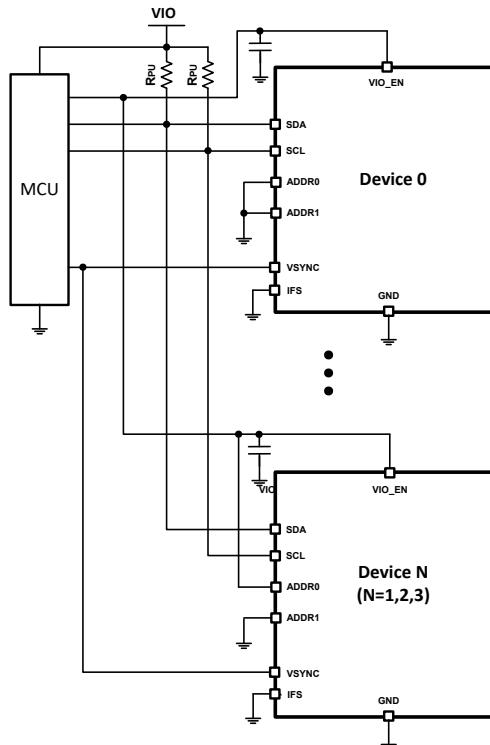
表 8-6. I²C Data Format

Address Byte1	Chip Address					Register Address		R/W
	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Independent	1	0	0	ADDR1	ADDR0	9 th bit	8 th bit	R: 1 W: 0
Broadcast	1	0	1	0	1			
Register Address								
Address Byte 2	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
	7 th bit	6 th bit	5 th bit	4 th bit	3 th bit	2 th bit	1 th bit	0 th bit

图 8-11. I²C Write Timing图 8-12. I²C Read Timing

Multiple Devices Connection

The LP5861 enters into I²C mode if IFS is connected to GND. The ADDR0/1 pin is used to select the unique I²C follower address for each device. The SCL and SDA lines must each have a pullup resistor (4.7 KΩ for 400 KHz, 2 KΩ for 1 MHz) placed somewhere on the line and remain HIGH even when the bus is idle. VIO_EN can either be connected with VIO power supply or GPIO. TI suggests to put one 1-nF cap as closer to VIO_EN pin as possible. Up to four LP5861 follower devices can share the same I²C bus by the different ADDR configurations.

图 8-13. I²C Multiple Devices Connection

SPI Interface

The LP5861 is compatible with SPI serial-bus specification, and it operates as a follower. The maximum frequency supported by LP5861 is 12 MHz.

SPI Data Transactions

MISO output is normally in a high impedance state. When the follower-select pin SS for the device is active (low) the MISO output is pulled low for read only. During write cycle MISO stays in high-impedance state. The

follower-select signal SS must be low during the cycle transmission. SS resets the interface when high. Data is clocked in on the rising edge of the SCLK clock signal, while data is clocked out on the falling edge of SCLK.

SPI Data Format

The address and data bits are transmitted MSB first with 8-bits length format in each cycle. Each transmission is started with Address Byte 1, which contains 8 higher bits of the register address. The Address Byte 2 is started with 2 lower bits of the register address and 1 read and write bit. The auto-increment feature allows writing and reading several consecutive registers within one transmission. If not consecutive, a new transmission must be started.

表 8-7. SPI Data Format

Address Byte 1	Register Address								
	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
	9 th bit	8 th bit	7 th bit	6 th bit	5 th bit	4 th bit	3 th bit	2 th bit	
Address Byte 2	Register Address								
	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
	1 th bit	0 th bit	R: 0 W: 1	Don't Care					

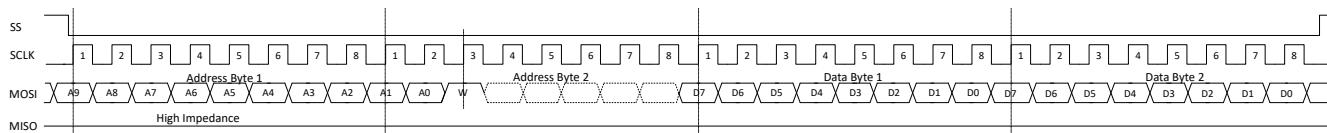


图 8-14. SPI Write Timing

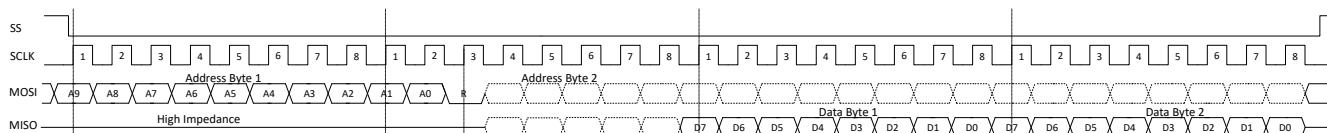


图 8-15. SPI Read Timing

Multiple Devices Connection

The device enters into SPI mode if IFS is pulled high to VIO through a pullup resistor (4.7K Ω recommended). VIO_EN can either be connected with VIO power supply or GPIO. TI suggests to put one 1-nF cap as closer to VIO_EN pin as possible. In SPI mode host can address as many devices as there are follower select pins on host.

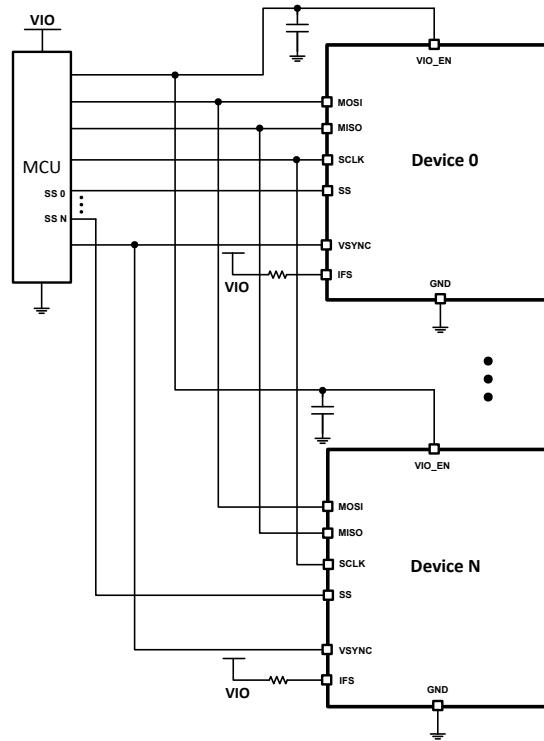


图 8-16. SPI Multiple Devices Connection

8.6 Register Maps

表 8-8 lists the memory-mapped registers of the device.

表 8-8. Register Section/Block Access Type Codes

Access Type	Code	Description
Read Type		
R	R	Read
RC	R C	Read to Clear
R-0	R -0	Read Returns 0s
Write Type		
W	W	Write
W0CP	W 0C P	W 0 to clear Requires privileged access
Reset or Default Value		
-n		Value after reset or the default value

Register Acronym	Address	Type	D7	D6	D5	D4	D3	D2	D1	D0	Default
Chip_en	000h	R/W	Reserved						Chip_EN		00h
Dev_initial	001h	R/W	Reserved					Data_Ref_Mode		PWM_Fre	5Eh
Dev_config1	002h	R/W	Reserved			PWM_Scale_Mode		PWM_Phase_Shift	Reserved	00h	
Dev_config2	003h	R/W	Comp_Group3		Comp_Group2		Comp_Group1		Reserved		00h
Dev_config3	004h	R/W	Reserved					Maximum_Current		Reserved	47h

Global_bri	005h	R/W	PWM_Global								FFh						
Group0_bri	006h	R/W	PWM_Group1								FFh						
Group1_bri	007h	R/W	PWM_Group2								FFh						
Group2_bri	008h	R/W	PWM_Group3								FFh						
R_current_set	009h	R/W	Reserved	CC_Group1								40h					
G_current_set	00Ah	R/W	Reserved	CC_Group2								40h					
B_current_set	00Bh	R/W	Reserved	CC_Group3								40h					
Dot_grp_sel0	00Ch	R/W	Dot CS3 group		Dot CS2 group		Dot CS1 group		Dot CS0 group		00h						
Dot_grp_sel1	00Dh	R/W	Dot CS7 group		Dot CS6 group		Dot CS5 group		Dot CS4 group		00h						
Dot_grp_sel2	00Eh	R/W	Dot CS11 group		Dot CS10 group		Dot CS9 group		Dot CS8 group		00h						
Dot_grp_sel3	00Fh	R/W	Dot CS15 group		Dot CS14 group		Dot CS13 group		Dot CS12 group		00h						
Dot_grp_sel4	010h	R/W	Reserved				Dot CS17 group		Dot CS16 group		00h						
Dot_onoff0	043h	R/W	Dot CS7 onoff	Dot CS6 onoff	Dot CS5 onoff	Dot CS4 onoff	Dot CS3 onoff	Dot CS2 onoff	Dot CS1 onoff	Dot CS0 onoff	FFh						
Dot_onoff1	044h	R/W	Dot CS15 onoff	Dot CS14 onoff	Dot CS13 onoff	Dot CS12 onoff	Dot CS11 onoff	Dot CS10 onoff	Dot CS9 onoff	Dot CS8 onoff	FFh						
Dot_onoff2	045h	R/W	Reserved						Dot CS17 onoff	Dot CS16 onoff	03h						
Fault_state	064h	R	Reserved						Global_L OD	Global_L SD	00h						
Dot_lod0	065h	R	Dot CS7 LOD	Dot CS6 LOD	Dot CS5 LOD	Dot CS4 LOD	Dot CS3 LOD	Dot CS2 LOD	Dot CS1 LOD	Dot CS0 LOD	00h						
Dot_lod1	066h	R	Dot CS15 LOD	Dot CS14 LOD	Dot CS13 LOD	Dot CS12 LOD	Dot CS11 LOD	Dot CS10 LOD	Dot CS9 LOD	Dot CS8 LOD	00h						
Dot_lod2	067h	R	Reserved						Dot CS17 LOD	Dot CS16 LOD	00h						
Dot_lsd0	086h	R	Dot CS7 LSD	Dot CS6 LSD	Dot CS5 LSD	Dot CS4 LSD	Dot CS3 LSD	Dot CS2 LSD	Dot CS1 LSD	Dot CS0 LSD	00h						
Dot_lsd1	087h	R	Dot CS15 LSD	Dot CS14 LSD	Dot CS13 LSD	Dot CS12 LSD	Dot CS11 LSD	Dot CS10 LSD	Dot CS9 LSD	Dot CS8 LSD	00h						
Dot_lsd2	088h	R	Reserved						Dot CS17 LSD	Dot CS16 LSD	00h						
LOD_clear	0A7h	W	Reserved				LOD_Clear				00h						
LSD_clear	0A8h	W	Reserved				LSD_Clear				00h						
Reset	0A9h	W	Reset										00h				
DC0	100h	R/W	LED dot current setting for Dot CS0										80h				
DC1	101h	R/W	LED dot current setting for Dot CS1										80h				
DC2	102h	R/W	LED dot current setting for Dot CS2										80h				
DC3	103h	R/W	LED dot current setting for Dot CS3										80h				
DC4	104h	R/W	LED dot current setting for Dot CS4										80h				
DC5	105h	R/W	LED dot current setting for Dot CS5										80h				
DC6	106h	R/W	LED dot current setting for Dot CS6										80h				
DC7	107h	R/W	LED dot current setting for Dot CS7										80h				
DC8	108h	R/W	LED dot current setting for Dot CS8										80h				
DC9	109h	R/W	LED dot current setting for Dot CS9										80h				
DC10	10Ah	R/W	LED dot current setting for Dot CS10										80h				
DC11	10Bh	R/W	LED dot current setting for Dot CS11										80h				
DC12	10Ch	R/W	LED dot current setting for Dot CS12										80h				
DC13	10Dh	R/W	LED dot current setting for Dot CS13										80h				
DC14	10Eh	R/W	LED dot current setting for Dot CS14										80h				

DC15	10Fh	R/W	LED dot current setting for Dot CS15	80h
DC16	110h	R/W	LED dot current setting for Dot CS16	80h
DC17	111h	R/W	LED dot current setting for Dot CS17	80h
pwm_bri0	200h	R/W	8-bit PWM for Dot CS0 OR 16-bit PWM lower 8 bits [7:0] for Dot CS0	00h
pwm_bri1	201h	R/W	8-bit PWM for Dot CS1 OR 16-bit PWM higher 8 bits [15:8] for Dot CS0	00h
pwm_bri2	202h	R/W	8-bit PWM for Dot CS2 OR 16-bit PWM lower 8 bits [7:0] for Dot CS1	00h
pwm_bri3	203h	R/W	8-bit PWM for Dot CS3 OR 16-bit PWM higher 8 bits [15:8] for Dot CS1	00h
pwm_bri4	204h	R/W	8-bit PWM for Dot CS4 OR 16-bit PWM lower 8 bits [7:0] for Dot CS2	00h
pwm_bri5	205h	R/W	8-bit PWM for Dot CS5 OR 16-bit PWM higher 8 bits [15:8] for Dot CS2	00h
pwm_bri6	206h	R/W	8-bit PWM for Dot CS6 OR 16-bit PWM lower 8 bits [7:0] for Dot CS3	00h
pwm_bri7	207h	R/W	8-bit PWM for Dot CS7 OR 16-bit PWM higher 8 bits [15:8] for Dot CS3	00h
pwm_bri8	208h	R/W	8-bit PWM for Dot CS8 OR 16-bit PWM lower 8 bits [7:0] for Dot CS4	00h
pwm_bri9	209h	R/W	8-bit PWM for Dot CS9 OR 16-bit PWM higher 8 bits [15:8] for Dot CS4	00h
pwm_bri10	20Ah	R/W	8-bit PWM for Dot CS10 OR 16-bit PWM lower 8 bits [7:0] for Dot CS5	00h
pwm_bri11	20Bh	R/W	8-bit PWM for Dot CS11 OR 16-bit PWM higher 8 bits [15:8] for Dot CS5	00h
pwm_bri12	20Ch	R/W	8-bit PWM for Dot CS12 OR 16-bit PWM lower 8 bits [7:0] for Dot CS6	00h
pwm_bri13	20Dh	R/W	8-bit PWM for Dot CS13 OR 16-bit PWM higher 8 bits [15:8] for Dot CS6	00h
pwm_bri14	20Eh	R/W	8-bit PWM for Dot CS14 OR 16-bit PWM lower 8 bits [7:0] for Dot CS7	00h
pwm_bri15	20Fh	R/W	8-bit PWM for Dot CS15 OR 16-bit PWM higher 8 bits [15:8] for Dot CS7	00h
pwm_bri16	210h	R/W	8-bit PWM for Dot CS16 OR 16-bit PWM lower 8 bits [7:0] for Dot CS8	00h
pwm_bri17	211h	R/W	8-bit PWM for Dot CS17 OR 16-bit PWM higher 8 bits [15:8] for Dot CS8	00h
pwm_bri18	212h	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS9	00h
pwm_bri19	213h	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS9	00h
pwm_bri20	214h	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS10	00h
pwm_bri21	215h	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS10	00h
pwm_bri22	216h	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS11	00h
pwm_bri23	217h	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS11	00h
pwm_bri24	218h	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS12	00h
pwm_bri25	219h	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS12	00h
pwm_bri26	21Ah	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS13	00h
pwm_bri27	21Bh	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS13	00h
pwm_bri28	21Ch	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS14	00h
pwm_bri29	21Dh	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS14	00h
pwm_bri30	21Eh	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS15	00h
pwm_bri31	21Fh	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS15	00h
pwm_bri32	220h	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS16	00h
pwm_bri33	221h	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS16	00h
pwm_bri34	222h	R/W	16-bit PWM lower 8 bits [7:0] for Dot CS17	00h
pwm_bri35	223h	R/W	16-bit PWM higher 8 bits [15:8] for Dot CS17	00h

8.6.1 CONFIG Registers

表 8-9 lists the CONFIG registers. All register offset addresses not listed in 表 8-9 must be considered as reserved locations and the register contents must not be modified.

表 8-9. CONFIG Registers

Address	Acronym	Register Name	Section
0h	Chip_en	Chip enable	Go
1h	Dev_initial	Device initialization	Go

表 8-9. CONFIG Registers (continued)

Address	Acronym	Register Name	Section
2h	Dev_config1	Device configuration register 1	Go
3h	Dev_config2	Device configuration register 2	Go
4h	Dev_config3	Device configuration register 3	Go

8.6.1.1 Chip_en Register (Address = 0h) [Default = 0h]

Chip_en is shown in [图 8-17](#) and described in [表 8-10](#).

Return to the [Summary table](#).

图 8-17. Chip_en Register

7	6	5	4	3	2	1	0
RESERVED							Chip_EN
R-0h							R/W-0h

表 8-10. Chip_en Register Field Descriptions

Bit	Field	Type	Default	Description
7-1	RESERVED	R	0h	Reserved
0	Chip_EN	R/W	0h	Chip enable 0h = Disabled 1h = Enabled

8.6.1.2 Dev_initial Register (Address = 1h) [Default = 5Eh]

Dev_initial is shown in [图 8-18](#) and described in [表 8-11](#).

Return to the [Summary table](#).

图 8-18. Dev_initial Register

7	6	5	4	3	2	1	0
RESERVED				Data_Ref_Mode		PWM_Fre	
R-Bh				R/W-3h		R/W-0h	

表 8-11. Dev_initial Register Field Descriptions

Bit	Field	Type	Default	Description
7-3	RESERVED	R	Bh	Reserved
2-1	Data_Ref_Mode	R/W	3h	Data refresh mode selection 0h = Mode 1 1h = Mode 2 2h = Mode 3 3h = Mode 3
0	PWM_Fre	R/W	0h	Output PWM frequency setting 0h = 125kHz 1h = 62.5kHz

8.6.1.3 Dev_config1 Register (Address = 2h) [Default = 0h]

Dev_config1 is shown in [图 8-19](#) and described in [表 8-12](#).

Return to the [Summary table](#).

图 8-19. Dev_config1 Register

7	6	5	4	3	2	1	0
RESERVED				PWM_Scale_Mode	PWM_Phase_Shift	RESERVED	
R-0h				R/W-0h	R/W-0h	R-0h	

表 8-12. Dev_config1 Register Field Descriptions

Bit	Field	Type	Default	Description
7-3	RESERVED	R	0h	Reserved
2	PWM_Scale_Mode	R/W	0h	Dimming scale setting of final PWM generator 0h = Linear scale dimming curve 1h = Exponential scale dimming curve
1	PWM_Phase_Shift	R/W	0h	PWM phase shift selection 0h = Phase shift off 1h = Phase shift on
0	RESERVED	R	0h	Reserved

8.6.1.4 Dev_config2 Register (Address = 3h) [Default = 0h]

Dev_config2 is shown in [图 8-20](#) and described in [表 8-13](#).

Return to the [Summary table](#).

图 8-20. Dev_config2 Register

7	6	5	4	3	2	1	0
Comp_Group3	Comp_Group2			Comp_Group1	RESERVED		
R/W-0h	R/W-0h			R/W-0h	R-0h		

表 8-13. Dev_config2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-6	Comp_Group3	R/W	0h	Low brightness compensation clock shift number setting for group1 0h = off 1h = 1 clock 2h = 2 clock 3h = 3 clock
5-4	Comp_Group2	R/W	0h	Low brightness compensation clock shift number setting for group2 0h = off 1h = 1 clock 2h = 2 clock 3h = 3 clock
3-2	Comp_Group1	R/W	0h	Low brightness compensation clock shift number setting for group3 0h = off 1h = 1 clock 2h = 2 clock 3h = 3 clock
1-0	RESERVED	R	0h	Reserved

8.6.1.5 Dev_config3 Register (Address = 4h) [Default = 57h]

Dev_config3 is shown in [图 8-21](#) and described in [表 8-14](#).

Return to the [Summary table](#).

图 8-21. Dev_config3 Register

7	6	5	4	3	2	1	0
RESERVED				Maximum_Current			RESERVED
R-5h			R/W-3h			R-1h	

表 8-14. Dev_config3 Register Field Descriptions

Bit	Field	Type	Default	Description
7-4	RESERVED	R	5h	Reserved
3-1	Maximum_Current	R/W	3h	Maximum current setting (MC) 0h = 3mA 1h = 5mA 2h = 10mA 3h = 15mA (Default) 4h = 20mA 5h = 30mA 6h = 40mA 7h = 50mA
0	RESERVED	R	1h	Reserved

8.6.2 GROUP Registers

表 8-15 lists the GROUP registers. All register offset addresses not listed in 表 8-15 must be considered as reserved locations and the register contents must not be modified.

表 8-15. GROUP Registers

Address	Acronym	Register Name	Section
5h	Master_bri	Global PWM configuration	Go
6h	Group0_bri	Group1 PWM configuration	Go
7h	Group1_bri	Group2 PWM configuration	Go
8h	Group2_bri	Group3 PWM configuration	Go
9h	R_current_set	Group1 current configuration	Go
Ah	G_current_set	Group2 current configuration	Go
Bh	B_current_set	Group3 current configuration	Go

8.6.2.1 Master_bri Register (Address = 5h) [Default = FFh]

Master_bri is shown in 图 8-22 and described in 表 8-16.

Return to the [Summary Table](#).

图 8-22. Master_bri Register

7	6	5	4	3	2	1	0
PWM_Global							
R/W-FFh							

表 8-16. Master_bri Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	PWM_Global	R/W	FFh	Global PWM setting

8.6.2.2 Group0_bri Register (Address = 6h) [Default = FFh]

Group0_bri is shown in 图 8-23 and described in 表 8-17.

Return to the [Summary Table](#).

图 8-23. Group0_bri Register

7	6	5	4	3	2	1	0
PWM_Group1							
R/W-FFh							

表 8-17. Group0_bri Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	PWM_Group1	R/W	FFh	Group1 PWM setting

8.6.2.3 Group1_bri Register (Address = 7h) [Default = FFh]

Group1_bri is shown in 图 8-24 and described in 表 8-18.

Return to the [Summary Table](#).

图 8-24. Group1_bri Register

7	6	5	4	3	2	1	0
---	---	---	---	---	---	---	---

图 8-24. Group1_bri Register (continued)

PWM_Group2

R/W-FFh

表 8-18. Group1_bri Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	PWM_Group2	R/W	FFh	Group2 PWM setting

8.6.2.4 Group2_bri Register (Address = 8h) [Default = FFh]

Group2_bri is shown in [图 8-25](#) and described in [表 8-19](#).

Return to the [Summary Table](#).

图 8-25. Group2_bri Register

7	6	5	4	3	2	1	0
PWM_Group3							
R/W-FFh							

表 8-19. Group2_bri Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	PWM_Group3	R/W	FFh	Group3 PWM setting

8.6.2.5 R_current_set Register (Address = 9h) [Default = 40h]

R_current_set is shown in [图 8-26](#) and described in [表 8-20](#).

Return to the [Summary Table](#).

图 8-26. R_current_set Register

7	6	5	4	3	2	1	0	
RESERVED		CC_Group1						
R-0h		R/W-40h						

表 8-20. R_current_set Register Field Descriptions

Bit	Field	Type	Default	Description
7	RESERVED	R	0h	Reserved
6-0	CC_Group1	R/W	40h	Color-group current setting (CC) of group 1 (CS0, CS3, CS6, CS9, CS12, CS15)

8.6.2.6 G_current_set Register (Address = Ah) [Default = 40h]

G_current_set is shown in [图 8-27](#) and described in [表 8-21](#).

Return to the [Summary Table](#).

图 8-27. G_current_set Register

7	6	5	4	3	2	1	0	
RESERVED		CC_Group2						
R-0h		R/W-40h						

表 8-21. G_current_set Register Field Descriptions

Bit	Field	Type	Default	Description
7	RESERVED	R	0h	Reserved
6-0	CC_Group2	R/W	40h	Color-group current setting (CC) of group 2 (CS1, CS4, CS7, CS10, CS13, CS16)

8.6.2.7 B_current_set Register (Address = Bh) [Default = 40h]

B_current_set is shown in [图 8-28](#) and described in [表 8-22](#).

Return to the [Summary Table](#).

图 8-28. B_current_set Register

7	6	5	4	3	2	1	0
RESERVED							CC_Group3
							R/W-40h

表 8-22. B_current_set Register Field Descriptions

Bit	Field	Type	Default	Description
7	RESERVED	R	0h	Reserved
6-0	CC_Group3	R/W	40h	Color-group current setting (CC) of group 3 (CS2, CS5, CS8, CS11, CS14, CS17)

8.6.3 DOTGROUP Registers

[表 8-23](#) lists the DOTGROUP registers. All register offset addresses not listed in [表 8-23](#) must be considered as reserved locations and the register contents must not be modified.

表 8-23. DOTGROUP Registers

Address	Acronym	Register Name	Section
Ch	Dot_grp_sel0	LED dot group selection register 0	Go
Dh	Dot_grp_sel1	LED dot group selection register 1	Go
Eh	Dot_grp_sel2	LED dot group selection register 2	Go
Fh	Dot_grp_sel3	LED dot group selection register 3	Go
10h	Dot_grp_sel4	LED dot group selection register 4	Go

8.6.3.1 Dot_grp_sel0 Register (Address = Ch) [Default = 0h]

Dot_grp_sel0 is shown in [图 8-29](#) and described in [表 8-24](#).

Return to the [Summary Table](#).

图 8-29. Dot_grp_sel0 Register

7	6	5	4	3	2	1	0
CS3_group		CS2_group		CS1_group		CS0_group	
R/W-0h		R/W-0h		R/W-0h		R/W-0h	

表 8-24. Dot_grp_sel0 Register Field Descriptions

Bit	Field	Type	Default	Description
7-6	CS3_group	R/W	0h	CS3 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

表 8-24. Dot_grp_sel0 Register Field Descriptions (continued)

Bit	Field	Type	Default	Description
5-4	CS2_group	R/W	0h	CS2 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
3-2	CS1_group	R/W	0h	CS1 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
1-0	CS0_group	R/W	0h	CS0 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

8.6.3.2 Dot_grp_sel1 Register (Address = Dh) [Default = 0h]

Dot_grp_sel1 is shown in [图 8-30](#) and described in [表 8-25](#).

Return to the [Summary Table](#).

图 8-30. Dot_grp_sel1 Register

7	6	5	4	3	2	1	0
CS7_group		CS6_group		CS5_group		CS4_group	
R/W-0h		R/W-0h		R/W-0h		R/W-0h	

表 8-25. Dot_grp_sel1 Register Field Descriptions

Bit	Field	Type	Default	Description
7-6	CS7_group	R/W	0h	CS7 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
5-4	CS6_group	R/W	0h	CS6 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
3-2	CS5_group	R/W	0h	CS5 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
1-0	CS4_group	R/W	0h	CS4 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

8.6.3.3 Dot_grp_sel2 Register (Address = Eh) [Default = 0h]

Dot_grp_sel2 is shown in [图 8-31](#) and described in [表 8-26](#).

Return to the [Summary Table](#).

图 8-31. Dot_grp_sel2 Register

7	6	5	4	3	2	1	0
CS11_group		CS10_group		CS9_group		CS8_group	
R/W-0h		R/W-0h		R/W-0h		R/W-0h	

表 8-26. Dot_grp_sel2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-6	CS11_group	R/W	0h	CS11 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
5-4	CS10_group	R/W	0h	CS10 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
3-2	CS9_group	R/W	0h	CS9 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
1-0	CS8_group	R/W	0h	CS8 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

8.6.3.4 Dot_grp_sel3 Register (Address = Fh) [Default = 0h]

Dot_grp_sel3 is shown in 图 8-32 and described in 表 8-27.

Return to the [Summary Table](#).

图 8-32. Dot_grp_sel3 Register

7	6	5	4	3	2	1	0
CS15_group		CS14_group		CS13_group		CS12_group	
R/W-0h		R/W-0h		R/W-0h		R/W-0h	

表 8-27. Dot_grp_sel3 Register Field Descriptions

Bit	Field	Type	Default	Description
7-6	CS15_group	R/W	0h	CS15 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
5-4	CS14_group	R/W	0h	CS14 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
3-2	CS13_group	R/W	0h	CS13 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

表 8-27. Dot_grp_sel3 Register Field Descriptions (continued)

Bit	Field	Type	Default	Description
1-0	CS12_group	R/W	0h	CS12 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

8.6.3.5 Dot_grp_sel4 Register (Address = 10h) [Default = 0h]Dot_grp_sel4 is shown in [图 8-33](#) and described in [表 8-28](#).Return to the [Summary Table](#).**图 8-33. Dot_grp_sel4 Register**

7	6	5	4	3	2	1	0
RESERVED				CS17_group	CS16_group		
R-0h				R/W-0h	R/W-0h		

表 8-28. Dot_grp_sel4 Register Field Descriptions

Bit	Field	Type	Default	Description
7-4	RESERVED	R	0h	Reserved
3-2	CS17_group	R/W	0h	CS17 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3
1-0	CS16_group	R/W	0h	CS16 group PWM control setting 0h = No group 1h = Group 1 2h = Group 2 3h = Group 3

8.6.4 DOTONOFF Registers

[表 8-29](#) lists the DOTONOFF registers. All register offset addresses not listed in [表 8-29](#) must be considered as reserved locations and the register contents must not be modified.

表 8-29. DOTONOFF Registers

Address	Acronym	Register Name	Section
43h	Dot_onoff0	LED dot ON/OFF selection register 0	Go
44h	Dot_onoff1	LED dot ON/OFF selection register 1	Go
45h	Dot_onoff2	LED dot ON/OFF selection register 2	Go

8.6.4.1 Dot_onoff0 Register (Address = 43h) [Default = FFh]Dot_onoff0 is shown in [图 8-34](#) and described in [表 8-30](#).Return to the [Summary Table](#).**图 8-34. Dot_onoff0 Register**

7	6	5	4	3	2	1	0
CS7_onoff	CS6_onoff	CS5_onoff	CS4_onoff	CS3_onoff	CS2_onoff	CS1_onoff	CS0_onoff
R/W-1h							

表 8-30. Dot_onoff0 Register Field Descriptions

Bit	Field	Type	Default	Description
7	CS7_onoff	R/W	1h	LED CS7 on/off setting 0h = Off 1h = On
6	CS6_onoff	R/W	1h	LED CS6 on/off setting 0h = Off 1h = On
5	CS5_onoff	R/W	1h	LED CS5 on/off setting 0h = Off 1h = On
4	CS4_onoff	R/W	1h	LED CS4 on/off setting 0h = Off 1h = On
3	CS3_onoff	R/W	1h	LED CS3 on/off setting 0h = Off 1h = On
2	CS2_onoff	R/W	1h	LED CS2 on/off setting 0h = Off 1h = On
1	CS1_onoff	R/W	1h	LED CS1 on/off setting 0h = Off 1h = On
0	CS0_onoff	R/W	1h	LED CS0 on/off setting 0h = Off 1h = On

8.6.4.2 Dot_onoff1 Register (Address = 44h) [Default = FFh]

Dot_onoff1 is shown in [图 8-35](#) and described in [表 8-31](#).

Return to the [Summary Table](#).

图 8-35. Dot_onoff1 Register

7	6	5	4	3	2	1	0
CS15_onoff	CS14_onoff	CS13_onoff	CS12_onoff	CS11_onoff	CS10_onoff	CS1_onoff	CS0_onoff
R/W-1h	R/W-1h	R/W-1h	R/W-1h	R/W-1h	R/W-1h	R/W-1h	R/W-1h

表 8-31. Dot_onoff1 Register Field Descriptions

Bit	Field	Type	Default	Description
7	CS15_onoff	R/W	1h	LED CS15 on/off setting 0h = Off 1h = On
6	CS14_onoff	R/W	1h	LED CS14 on/off setting 0h = Off 1h = On
5	CS13_onoff	R/W	1h	LED CS13 on/off setting 0h = Off 1h = On
4	CS12_onoff	R/W	1h	LED CS12 on/off setting 0h = Off 1h = On
3	CS11_onoff	R/W	1h	LED CS11 on/off setting 0h = Off 1h = On
2	CS10_onoff	R/W	1h	LED CS10 on/off setting 0h = Off 1h = On

表 8-31. Dot_onoff1 Register Field Descriptions (continued)

Bit	Field	Type	Default	Description
1	CS1_onoff	R/W	1h	LED CS9 on/off setting 0h = Off 1h = On
0	CS0_onoff	R/W	1h	LED CS8 on/off setting 0h = Off 1h = On

8.6.4.3 Dot_onoff2 Register (Address = 45h) [Default = 3h]

Dot_onoff2 is shown in [图 8-36](#) and described in [表 8-32](#).

Return to the [Summary Table](#).

图 8-36. Dot_onoff2 Register

7	6	5	4	3	2	1	0
RESERVED						CS17_onoff	CS16_onoff
R-0h						R/W-1h	R/W-1h

表 8-32. Dot_onoff2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-2	RESERVED	R	0h	Reserved
1	CS17_onoff	R/W	1h	LED CS17 on/off setting 0h = Off 1h = On
0	CS16_onoff	R/W	1h	LED CS16 on/off setting 0h = Off 1h = On

8.6.5 FAULT Registers

[表 8-33](#) lists the FAULT registers, including Fault_state registers, LOD registers and LSD registers. All register offset addresses not listed in [表 8-33](#) must be considered as reserved locations and the register contents must not be modified.

表 8-33. FAULT Registers

Address	Acronym	Register Name	Section
64h	Fault_state	Global LOD/LSD indication register	Go
65h	Dot_lod0	LED dot LOD indication register 0	Go
66h	Dot_lod1	LED dot LOD indication register 1	Go
67h	Dot_lod2	LED dot LOD indication register 2	Go
86h	Dot_lsd0	LED dot LSD indication register 0	Go
87h	Dot_lsd1	LED dot LSD indication register 1	Go
88h	Dot_lsd2	LED dot LSD indication register 2	Go

8.6.5.1 Fault_state Register (Address = 64h) [Default = 0h]

Fault_state is shown in [图 8-37](#) and described in [表 8-34](#).

Return to the [Summary Table](#).

图 8-37. Fault_state Register

7	6	5	4	3	2	1	0
---	---	---	---	---	---	---	---

图 8-37. Fault_state Register (continued)

RESERVED	Global_LOD	Global_LSD
R-0h	R-0h	R-0h

表 8-34. Fault_state Register Field Descriptions

Bit	Field	Type	Default	Description
7-2	RESERVED	R	0h	Reserved
1	Global_LOD	R	0h	LOD indication bit if there is open fault detected at any LED dot 0h = Not open 1h = Open
0	Global_LSD	R	0h	LSD indication bit if there is short fault detected at any LED dot 0h = Not short 1h = Short

8.6.5.2 Dot_lod0 Register (Address = 65h) [Default = 0h]

Dot_lod0 is shown in [图 8-38](#) and described in [表 8-35](#).

Return to the [Summary Table](#).

图 8-38. Dot_lod0 Register

7	6	5	4	3	2	1	0
CS7_LOD_stat e	CS6_LOD_stat e	CS5_LOD_stat e	CS4_LOD_stat e	CS3_LOD_stat e	CS2_LOD_stat e	CS1_LOD_stat e	CS0_LOD_stat e
R-0h							

表 8-35. Dot_lod0 Register Field Descriptions

Bit	Field	Type	Default	Description
7	CS7_LOD_state	R	0h	CS7 LOD state 0h = Not open 1h = Open
6	CS6_LOD_state	R	0h	CS6 LOD state 0h = Not open 1h = Open
5	CS5_LOD_state	R	0h	CS5 LOD state 0h = Not open 1h = Open
4	CS4_LOD_state	R	0h	CS4 LOD state 0h = Not open 1h = Open
3	CS3_LOD_state	R	0h	CS3 LOD state 0h = Not open 1h = Open
2	CS2_LOD_state	R	0h	CS2 LOD state 0h = Not open 1h = Open
1	CS1_LOD_state	R	0h	CS1 LOD state 0h = Not open 1h = Open
0	CS0_LOD_state	R	0h	CS0 LOD state 0h = Not open 1h = Open

8.6.5.3 Dot_lod1 Register (Address = 66h) [Default = 0h]

Dot_lod1 is shown in [图 8-39](#) and described in [表 8-36](#).

Return to the [Summary Table](#).

图 8-39. Dot_lod1 Register

7	6	5	4	3	2	1	0
CS15_LOD_st ate	CS14_LOD_st ate	CS13_LOD_st ate	CS12_LOD_st ate	CS11_LOD_st ate	CS10_LOD_st ate	CS9_LOD_st ate	CS8_LOD_st ate
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

表 8-36. Dot_lod1 Register Field Descriptions

Bit	Field	Type	Default	Description
7	CS15_LOD_state	R	0h	CS15 LOD state 0h = Not open 1h = Open

表 8-36. Dot_Iod1 Register Field Descriptions (continued)

Bit	Field	Type	Default	Description
6	CS14_LOD_state	R	0h	CS14 LOD state 0h = Not open 1h = Open
5	CS13_LOD_state	R	0h	CS13 LOD state 0h = Not open 1h = Open
4	CS12_LOD_state	R	0h	CS12 LOD state 0h = Not open 1h = Open
3	CS11_LOD_state	R	0h	CS11 LOD state 0h = Not open 1h = Open
2	CS10_LOD_state	R	0h	CS10 LOD state 0h = Not open 1h = Open
1	CS9_LOD_state	R	0h	CS9 LOD state 0h = Not open 1h = Open
0	CS8_LOD_state	R	0h	CS8 LOD state 0h = Not open 1h = Open

8.6.5.4 Dot_Iod2 Register (Address = 67h) [Default = 0h]

Dot_Iod2 is shown in [图 8-40](#) and described in [表 8-37](#).

Return to the [Summary Table](#).

图 8-40. Dot_Iod2 Register

7	6	5	4	3	2	1	0
RESERVED						CS17_LOD_state	CS16_LOD_state
R-0h						R-0h	R-0h

表 8-37. Dot_Iod2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-2	RESERVED	R	0h	Reserved
1	CS17_LOD_state	R	0h	CS17 LOD state 0h = Not open 1h = Open
0	CS16_LOD_state	R	0h	CS16 LOD state 0h = Not open 1h = Open

8.6.5.5 Dot_Lsd0 Register (Address = 86h) [Default = 0h]

Dot_Lsd0 is shown in [图 8-41](#) and described in [表 8-38](#).

Return to the [Summary Table](#).

图 8-41. Dot_Lsd0 Register

7	6	5	4	3	2	1	0
CS7_LSD_state	CS6_LSD_state	CS5_LSD_state	CS4_LSD_state	CS3_LSD_state	CS2_LSD_state	CS1_LSD_state	CS0_LSD_state
R-0h							

表 8-38. Dot_Lsd0 Register Field Descriptions

Bit	Field	Type	Default	Description
7	CS7_LSD_state	R	0h	CS7 LSD state 0h = Not short 1h = Short
6	CS6_LSD_state	R	0h	CS6 LSD state 0h = Not short 1h = Short
5	CS5_LSD_state	R	0h	CS5 LSD state 0h = Not short 1h = Short
4	CS4_LSD_state	R	0h	CS4 LSD state 0h = Not short 1h = Short
3	CS3_LSD_state	R	0h	CS3 LSD state 0h = Not short 1h = Short
2	CS2_LSD_state	R	0h	CS2 LSD state 0h = Not short 1h = Short
1	CS1_LSD_state	R	0h	CS1 LSD state 0h = Not short 1h = Short
0	CS0_LSD_state	R	0h	CS0 LSD state 0h = Not short 1h = Short

8.6.5.6 Dot_Lsd1 Register (Address = 87h) [Default = 0h]

Dot_Lsd1 is shown in [图 8-42](#) and described in [表 8-39](#).

Return to the [Summary Table](#).

图 8-42. Dot_Lsd1 Register

7	6	5	4	3	2	1	0
CS15_LSD_stat e	CS14_LSD_stat e	CS13_LSD_stat e	CS12_LSD_stat e	CS11_LSD_stat e	CS10_LSD_stat e	CS9_LSD_state	CS8_LSD_state
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

表 8-39. Dot_Lsd1 Register Field Descriptions

Bit	Field	Type	Default	Description
7	CS15_LSD_state	R	0h	CS15 LSD state 0h = Not short 1h = Short
6	CS14_LSD_state	R	0h	CS14 LSD state 0h = Not short 1h = Short

表 8-39. Dot_Lsd1 Register Field Descriptions (continued)

Bit	Field	Type	Default	Description
5	CS13_LSD_state	R	0h	CS13 LSD state 0h = Not short 1h = Short
4	CS12_LSD_state	R	0h	CS12 LSD state 0h = Not short 1h = Short
3	CS11_LSD_state	R	0h	CS11 LSD state 0h = Not short 1h = Short
2	CS10_LSD_state	R	0h	CS10 LSD state 0h = Not short 1h = Short
1	CS9_LSD_state	R	0h	CS9 LSD state 0h = Not short 1h = Short
0	CS8_LSD_state	R	0h	CS8 LSD state 0h = Not short 1h = Short

8.6.5.7 Dot_Lsd2 Register (Address = 88h) [Default = 0h]

Dot_Lsd2 is shown in [图 8-43](#) and described in [表 8-40](#).

Return to the [Summary Table](#).

图 8-43. Dot_Lsd2 Register

7	6	5	4	3	2	1	0
RESERVED					CS17_LSD_stat e	CS16_LSD_stat e	
R-0h					R-0h	R-0h	

表 8-40. Dot_Lsd2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-2	RESERVED	R	0h	Reserved
1	CS17_LSD_state	R	0h	CS17 LSD state 0h = Not short 1h = Short
0	CS16_LSD_state	R	0h	CS16 LSD state 0h = Not short 1h = Short

8.6.6 RESET Registers

[表 8-41](#) lists the RESET registers, including LOD_CLR registers, LSD_CLR registers and Reset registers. All register offset addresses not listed in [表 8-41](#) must be considered as reserved locations and the register contents must not be modified.

表 8-41. RESET Registers

Address	Acronym	Register Name	Section
A7h	LOD_clear	LOD flag clear register	Go
A8h	LSD_clear	LSD flag clear register	Go
A9h	Reset	Software reset register	Go

8.6.6.1 LOD_clear Register (Address = A7h) [Default = 0h]

LOD_clear is shown in [图 8-44](#) and described in [表 8-42](#).

Return to the [Summary Table](#).

图 8-44. LOD_clear Register

7	6	5	4	3	2	1	0
RESERVED				LOD_Clear			
R-0h				W-0h			

表 8-42. LOD_clear Register Field Descriptions

Bit	Field	Type	Default	Description
7-4	RESERVED	R	0h	Reserved
3-0	LOD_Clear	W	0h	Write Fh to clear all LOD indication bits

8.6.6.2 LSD_clear Register (Address = A8h) [Default = 0h]

LSD_clear is shown in [图 8-45](#) and described in [表 8-43](#).

Return to the [Summary Table](#).

图 8-45. LSD_clear Register

7	6	5	4	3	2	1	0
RESERVED				LSD_Clear			
R-0h				W-0h			

表 8-43. LSD_clear Register Field Descriptions

Bit	Field	Type	Default	Description
7-4	RESERVED	R	0h	Reserved
3-0	LSD_Clear	W	0h	Write Fh to clear all LSD indication bits

8.6.6.3 Reset Register (Address = A9h) [Default = 0h]

Reset is shown in [图 8-46](#) and described in [表 8-44](#).

Return to the [Summary Table](#).

图 8-46. Reset Register

7	6	5	4	3	2	1	0
Reset				W-0h			

表 8-44. Reset Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	Reset	W	0h	Write FFh to reset the device

8.6.7 DC Registers

[表 8-45](#) lists the DC registers. All register offset addresses not listed in [表 8-45](#) must be considered as reserved locations and the register contents must not be modified.

表 8-45. DC Registers

Address	Acronym	Register Name	Section
100h	DC0	LED dot current setting for Dot L0-CS0	Go
101h	DC1	LED dot current setting for Dot L0-CS1	Go
102h	DC2	LED dot current setting for Dot L0-CS2	Go
103h	DC3	LED dot current setting for Dot L0-CS3	Go
104h	DC4	LED dot current setting for Dot L0-CS4	Go
105h	DC5	LED dot current setting for Dot L0-CS5	Go
106h	DC6	LED dot current setting for Dot L0-CS6	Go
107h	DC7	LED dot current setting for Dot L0-CS7	Go
108h	DC8	LED dot current setting for Dot L0-CS8	Go
109h	DC9	LED dot current setting for Dot L0-CS9	Go
10Ah	DC10	LED dot current setting for Dot L0-CS10	Go
10Bh	DC11	LED dot current setting for Dot L0-CS11	Go
10Ch	DC12	LED dot current setting for Dot L0-CS12	Go
10Dh	DC13	LED dot current setting for Dot L0-CS13	Go
10Eh	DC14	LED dot current setting for Dot L0-CS14	Go
10Fh	DC15	LED dot current setting for Dot L0-CS15	Go
110h	DC16	LED dot current setting for Dot L0-CS16	Go
111h	DC17	LED dot current setting for Dot L0-CS17	Go

8.6.7.1 DC0 Register (Address = 100h) [Default = 80h]

DC0 is shown in [图 8-47](#) and described in [表 8-46](#).

Return to the [Summary Table](#).

图 8-47. DC0 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS0							
R/W-80h							

表 8-46. DC0 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS0	R/W	80h	8-bits constant current value for CS0

8.6.7.2 DC1 Register (Address = 101h) [Default = 80h]

DC1 is shown in [图 8-48](#) and described in [表 8-47](#).

Return to the [Summary Table](#).

图 8-48. DC1 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS1							
R/W-80h							

表 8-47. DC1 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS1	R/W	80h	8-bits constant current value for CS1

8.6.7.3 DC2 Register (Address = 102h) [Default = 80h]

DC2 is shown in [图 8-49](#) and described in [表 8-48](#).

Return to the [Summary Table](#).

图 8-49. DC2 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS2							
R/W-80h							

表 8-48. DC2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS2	R/W	80h	8-bits constant current value for CS2

8.6.7.4 DC3 Register (Address = 103h) [Default = 80h]

DC3 is shown in [图 8-50](#) and described in [表 8-49](#).

Return to the [Summary Table](#).

图 8-50. DC3 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS3							
R/W-80h							

表 8-49. DC3 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS3	R/W	80h	8-bits constant current value for CS3

8.6.7.5 DC4 Register (Address = 104h) [Default = 80h]DC4 is shown in [图 8-51](#) and described in [表 8-50](#).Return to the [Summary Table](#).**图 8-51. DC4 Register**

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS4							
R/W-80h							

表 8-50. DC4 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS4	R/W	80h	8-bits constant current value for CS4

8.6.7.6 DC5 Register (Address = 105h) [Default = 80h]DC5 is shown in [图 8-52](#) and described in [表 8-51](#).Return to the [Summary Table](#).**图 8-52. DC5 Register**

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS5							
R/W-80h							

表 8-51. DC5 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS5	R/W	80h	8-bits constant current value for CS5

8.6.7.7 DC6 Register (Address = 106h) [Default = 80h]DC6 is shown in [图 8-53](#) and described in [表 8-52](#).Return to the [Summary Table](#).**图 8-53. DC6 Register**

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS6							
R/W-80h							

表 8-52. DC6 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS6	R/W	80h	8-bits constant current value for CS6

8.6.7.8 DC7 Register (Address = 107h) [Default = 80h]

 DC7 is shown in [图 8-54](#) and described in [表 8-53](#).

 Return to the [Summary Table](#).

图 8-54. DC7 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS7							
R/W-80h							

表 8-53. DC7 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS7	R/W	80h	8-bits constant current value for CS7

8.6.7.9 DC8 Register (Address = 108h) [Default = 80h]

 DC8 is shown in [图 8-55](#) and described in [表 8-54](#).

 Return to the [Summary Table](#).

图 8-55. DC8 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS8							
R/W-80h							

表 8-54. DC8 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS8	R/W	80h	8-bits constant current value for CS8

8.6.7.10 DC9 Register (Address = 109h) [Default = 80h]

 DC9 is shown in [图 8-56](#) and described in [表 8-55](#).

 Return to the [Summary Table](#).

图 8-56. DC9 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS9							
R/W-80h							

表 8-55. DC9 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS9	R/W	80h	8-bits constant current value for CS9

8.6.7.11 DC10 Register (Address = 10Ah) [Default = 80h]

DC10 is shown in [图 8-57](#) and described in [表 8-56](#).

Return to the [Summary Table](#).

图 8-57. DC10 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS10							
R/W-80h							

表 8-56. DC10 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS10	R/W	80h	8-bits constant current value for CS10

8.6.7.12 DC11 Register (Address = 10Bh) [Default = 80h]

DC11 is shown in [图 8-58](#) and described in [表 8-57](#).

Return to the [Summary Table](#).

图 8-58. DC11 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS11							
R/W-80h							

表 8-57. DC11 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS11	R/W	80h	8-bits constant current value for CS11

8.6.7.13 DC12 Register (Address = 10Ch) [Default = 80h]

DC12 is shown in [图 8-59](#) and described in [表 8-58](#).

Return to the [Summary Table](#).

图 8-59. DC12 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS12							
R/W-80h							

表 8-58. DC12 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS12	R/W	80h	8-bits constant current value for CS12

8.6.7.14 DC13 Register (Address = 10Dh) [Default = 80h]

DC13 is shown in [图 8-60](#) and described in [表 8-59](#).

Return to the [Summary Table](#).

图 8-60. DC13 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS13							
R/W-80h							

表 8-59. DC13 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS13	R/W	80h	8-bits constant current value for CS13

8.6.7.15 DC14 Register (Address = 10Eh) [Default = 80h]

DC14 is shown in [图 8-61](#) and described in [表 8-60](#).

Return to the [Summary Table](#).

图 8-61. DC14 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS14							
R/W-80h							

表 8-60. DC14 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS14	R/W	80h	8-bits constant current value for CS14

8.6.7.16 DC15 Register (Address = 10Fh) [Default = 80h]

DC15 is shown in [图 8-62](#) and described in [表 8-61](#).

Return to the [Summary Table](#).

图 8-62. DC15 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS15							
R/W-80h							

表 8-61. DC15 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS15	R/W	80h	8-bits constant current value for CS15

8.6.7.17 DC16 Register (Address = 110h) [Default = 80h]

DC16 is shown in [图 8-63](#) and described in [表 8-62](#).

Return to the [Summary Table](#).

图 8-63. DC16 Register

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS16							
R/W-80h							

表 8-62. DC16 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS16	R/W	80h	8-bits constant current value for CS16

8.6.7.18 DC17 Register (Address = 111h) [Default = 80h]DC17 is shown in [图 8-64](#) and described in [表 8-63](#).Return to the [Summary Table](#).**图 8-64. DC17 Register**

7	6	5	4	3	2	1	0
LED_dot_current_setting_for_CS17							
R/W-80h							

表 8-63. DC17 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	LED_dot_current_setting_f or_CS17	R/W	80h	8-bits constant current value for CS17

8.6.8 PWM Registers

[表 8-64](#) lists the PWM registers. All register offset addresses not listed in [表 8-64](#) must be considered as reserved locations and the register contents must not be modified.

表 8-64. PWM Registers

Address	Acronym	Register Name	Section
200h	pwm_bri0	8-bits PWM for CS0 OR 16-bits PWM lower 8 bits [7:0] for CS0	Go
201h	pwm_bri1	8-bits PWM for CS1 OR 16-bits PWM higher 8 bits [15:8] for CS0	Go
202h	pwm_bri2	8-bits PWM for CS2 OR 16-bits PWM lower 8 bits [7:0] for CS1	Go
203h	pwm_bri3	8-bits PWM for CS3 OR 16-bits PWM higher 8 bits [15:8] for CS1	Go
204h	pwm_bri4	8-bits PWM for CS4 OR 16-bits PWM lower 8 bits [7:0] for CS2	Go
205h	pwm_bri5	8-bits PWM for CS5 OR 16-bits PWM higher 8 bits [15:8] for CS2	Go
206h	pwm_bri6	8-bits PWM for CS6 OR 16-bits PWM lower 8 bits [7:0] for CS3	Go
207h	pwm_bri7	8-bits PWM for CS7 OR 16-bits PWM higher 8 bits [15:8] for CS3	Go
208h	pwm_bri8	8-bits PWM for CS8 OR 16-bits PWM lower 8 bits [7:0] for CS4	Go
209h	pwm_bri9	8-bits PWM for CS9 OR 16-bits PWM higher 8 bits [15:8] for CS4	Go
20Ah	pwm_bri10	8-bits PWM for CS10 OR 16-bits PWM lower 8 bits [7:0] for CS5	Go
20Bh	pwm_bri11	8-bits PWM for CS11 OR 16-bits PWM higher 8 bits [15:8] for CS5	Go
20Ch	pwm_bri12	8-bits PWM for CS12 OR 16-bits PWM lower 8 bits [7:0] for CS6	Go

表 8-64. PWM Registers (continued)

Address	Acronym	Register Name	Section
20Dh	pwm_bri13	8-bits PWM for CS13 OR 16-bits PWM higher 8 bits [15:8] for CS6	Go
20Eh	pwm_bri14	8-bits PWM for CS14 OR 16-bits PWM lower 8 bits [7:0] for CS7	Go
20Fh	pwm_bri15	8-bits PWM for CS15 OR 16-bits PWM higher 8 bits [15:8] for CS7	Go
210h	pwm_bri16	8-bits PWM for CS16 OR 16-bits PWM lower 8 bits [7:0] for CS8	Go
211h	pwm_bri17	8-bits PWM for CS17 OR 16-bits PWM higher 8 bits [15:8] for CS8	Go
212h	pwm_bri18	16-bits PWM lower 8 bits [7:0] for CS9	Go
213h	pwm_bri19	16-bits PWM higher 8 bits [15:8] for CS9	Go
214h	pwm_bri20	16-bits PWM lower 8 bits [7:0] for CS10	Go
215h	pwm_bri21	16-bits PWM higher 8 bits [15:8] for CS10	Go
216h	pwm_bri22	16-bits PWM lower 8 bits [7:0] for CS11	Go
217h	pwm_bri23	16-bits PWM higher 8 bits [15:8] for CS11	Go
218h	pwm_bri24	16-bits PWM lower 8 bits [7:0] for CS12	Go
219h	pwm_bri25	16-bits PWM higher 8 bits [15:8] for CS12	Go
21Ah	pwm_bri26	16-bits PWM lower 8 bits [7:0] for CS13	Go
21Bh	pwm_bri27	16-bits PWM higher 8 bits [15:8] for CS13	Go
21Ch	pwm_bri28	16-bits PWM lower 8 bits [7:0] for CS14	Go
21Dh	pwm_bri29	16-bits PWM higher 8 bits [15:8] for CS14	Go
21Eh	pwm_bri30	16-bits PWM lower 8 bits [7:0] for CS15	Go
21Fh	pwm_bri31	16-bits PWM higher 8 bits [15:8] for CS15	Go
220h	pwm_bri32	16-bits PWM lower 8 bits [7:0] for CS16	Go
221h	pwm_bri33	16-bits PWM higher 8 bits [15:8] for CS16	Go
222h	pwm_bri34	16-bits PWM lower 8 bits [7:0] for CS17	Go
223h	pwm_bri35	16-bits PWM higher 8 bits [15:8] for CS17	Go

8.6.8.1 pwm_bri0 Register (Address = 200h) [Default = 0h]

pwm_bri0 is shown in [图 8-65](#) and described in [表 8-65](#).

Return to the [Summary Table](#).

图 8-65. pwm_bri0 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS0_OR_16-bits_PWM_lower_8_bits_7:0_for_CS0							
R/W-0h							

表 8-65. pwm_bri0 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS0_OR_16-bits_PWM_lower_8_bits_7:0_for_CS0	R/W	0h	8-bits PWM for CS0 OR 16-bits PWM lower 8 bits [7:0] for CS0

8.6.8.2 pwm_bri1 Register (Address = 201h) [Default = 0h]

pwm_bri1 is shown in [图 8-66](#) and described in [表 8-66](#).

Return to the [Summary Table](#).

图 8-66. pwm_bri1 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS1_OR_16-bits_PWM_higher_8_bits_15:8_for_CS0							
R/W-0h							

表 8-66. pwm_bri1 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS1_OR_16-bits_PWM_higher_8_bits_15:8_for_CS0	R/W	0h	8-bits PWM for CS1 OR 16-bits PWM higher 8 bits [15:8] for CS0

8.6.8.3 pwm_bri2 Register (Address = 202h) [Default = 0h]

pwm_bri2 is shown in [图 8-67](#) and described in [表 8-67](#).

Return to the [Summary Table](#).

图 8-67. pwm_bri2 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS2_OR_16-bits_PWM_lower_8_bits_7:0_for_CS1							
R/W-0h							

表 8-67. pwm_bri2 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS2_OR_16-bits_PWM_lower_8_bits_7:0_for_CS1	R/W	0h	8-bits PWM for CS2 OR 16-bits PWM lower 8 bits [7:0] for CS1

8.6.8.4 pwm_bri3 Register (Address = 203h) [Default = 0h]

pwm_bri3 is shown in [图 8-68](#) and described in [表 8-68](#).

Return to the [Summary Table](#).

图 8-68. pwm_bri3 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS3_OR_16-bits_PWM_higher_8_bits_15:8_for_CS1							
R/W-0h							

表 8-68. pwm_bri3 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS3_OR_16-bits_PWM_higher_8_bits_15:8_for_CS1	R/W	0h	8-bits PWM for CS3 OR 16-bits PWM higher 8 bits [15:8] for CS1

8.6.8.5 pwm_bri4 Register (Address = 204h) [Default = 0h]

pwm_bri4 is shown in [图 8-69](#) and described in [表 8-69](#).

Return to the [Summary Table](#).

图 8-69. pwm_bri4 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS4_OR_16-bits_PWM_lower_8_bits_7:0_for_CS2							
R/W-0h							

表 8-69. pwm_bri4 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS4_OR_16-bits_PWM_lower_8_bits_7:0_for_CS2	R/W	0h	8-bits PWM for CS4 OR 16-bits PWM lower 8 bits [7:0] for CS2

8.6.8.6 pwm_bri5 Register (Address = 205h) [Default = 0h]

pwm_bri5 is shown in [图 8-70](#) and described in [表 8-70](#).

Return to the [Summary Table](#).

图 8-70. pwm_bri5 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS5_OR_16-bits_PWM_higher_8_bits_15:8_for_CS2							
R/W-0h							

表 8-70. pwm_bri5 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS5_OR_16-bits_PWM_higher_8_bits_15:8_for_CS2	R/W	0h	8-bits PWM for CS5 OR 16-bits PWM higher 8 bits [15:8] for CS2

8.6.8.7 pwm_bri6 Register (Address = 206h) [Default = 0h]

pwm_bri6 is shown in [图 8-71](#) and described in [表 8-71](#).

Return to the [Summary Table](#).

图 8-71. pwm_bri6 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS6_OR_16-bits_PWM_lower_8_bits_7:0_for_CS3							
R/W-0h							

表 8-71. pwm_bri6 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS6_OR_16-bits_PWM_lower_8_bits_7:0_for_CS3	R/W	0h	8-bits PWM for CS6 OR 16-bits PWM lower 8 bits [7:0] for CS3

8.6.8.8 pwm_bri7 Register (Address = 207h) [Default = 0h]

pwm_bri7 is shown in [图 8-72](#) and described in [表 8-72](#).

Return to the [Summary Table](#).

图 8-72. pwm_bri7 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS7_OR_16-bits_PWM_higher_8_bits_15:8_for_CS3							
R/W-0h							

表 8-72. pwm_bri7 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS7_OR_16-bits_PWM_higher_8_bits_15:8_for_CS3	R/W	0h	8-bits PWM for CS7 OR 16-bits PWM higher 8 bits [15:8] for CS3

8.6.8.9 pwm_bri8 Register (Address = 208h) [Default = 0h]

pwm_bri8 is shown in [图 8-73](#) and described in [表 8-73](#).

Return to the [Summary Table](#).

图 8-73. pwm_bri8 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS8_OR_16-bits_PWM_lower_8_bits_7:0_for_CS4							
R/W-0h							

表 8-73. pwm_bri8 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS8_OR_16-bits_PWM_lower_8_bits_7:0_for_CS4	R/W	0h	8-bits PWM for CS8 OR 16-bits PWM lower 8 bits [7:0] for CS4

8.6.8.10 pwm_bri9 Register (Address = 209h) [Default = 0h]

pwm_bri9 is shown in [图 8-74](#) and described in [表 8-74](#).

Return to the [Summary Table](#).

图 8-74. pwm_bri9 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS9_OR_16-bits_PWM_higher_8_bits_15:8_for_CS4							
R/W-0h							

表 8-74. pwm_bri9 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS9_OR_16-bits_PWM_higher_8_bits_15:8_for_CS4	R/W	0h	8-bits PWM for CS9 OR 16-bits PWM higher 8 bits [15:8] for CS4

8.6.8.11 pwm_bri10 Register (Address = 20Ah) [Default = 0h]

pwm_bri10 is shown in [图 8-75](#) and described in [表 8-75](#).

Return to the [Summary Table](#).

图 8-75. pwm_bri10 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS10_OR_16-bits_PWM_lower_8_bits_7:0_for_CS5							
R/W-0h							

表 8-75. pwm_bri10 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS10_OR_16-bits_PWM_lower_8_bits_7:0_for_CS5	R/W	0h	8-bits PWM for CS10 OR 16-bits PWM lower 8 bits [7:0] for CS5

8.6.8.12 pwm_bri11 Register (Address = 20Bh) [Default = 0h]

pwm_bri11 is shown in [图 8-76](#) and described in [表 8-76](#).

Return to the [Summary Table](#).

图 8-76. pwm_bri11 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS11_OR_16-bits_PWM_higher_8_bits_15:8_for_CS5							
R/W-0h							

表 8-76. pwm_bri11 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS11_OR_16-bits_PWM_higher_8_bits_15:8_for_CS5	R/W	0h	8-bits PWM for CS11 OR 16-bits PWM higher 8 bits [15:8] for CS5

8.6.8.13 pwm_bri12 Register (Address = 20Ch) [Default = 0h]

pwm_bri12 is shown in [图 8-77](#) and described in [表 8-77](#).

Return to the [Summary Table](#).

图 8-77. pwm_bri12 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS12_OR_16-bits_PWM_lower_8_bits_7:0_for_CS6							
R/W-0h							

表 8-77. pwm_bri12 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS12_OR_16-bits_PWM_lower_8_bits_7:0_for_CS6	R/W	0h	8-bits PWM for CS12 OR 16-bits PWM lower 8 bits [7:0] for CS6

8.6.8.14 pwm_bri13 Register (Address = 20Dh) [Default = 0h]

pwm_bri13 is shown in [图 8-78](#) and described in [表 8-78](#).

Return to the [Summary Table](#).

图 8-78. pwm_bri13 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS13_OR_16-bits_PWM_higher_8_bits_15:8_for_CS6							
R/W-0h							

表 8-78. pwm_bri13 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS13_OR_16-bits_PWM_higher_8_bits_15:8_for_CS6	R/W	0h	8-bits PWM for CS13 OR 16-bits PWM higher 8 bits [15:8] for CS6

8.6.8.15 pwm_bri14 Register (Address = 20Eh) [Default = 0h]

pwm_bri14 is shown in [图 8-79](#) and described in [表 8-79](#).

Return to the [Summary Table](#).

图 8-79. pwm_bri14 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS14_OR_16-bits_PWM_lower_8_bits_7:0_for_CS7							
R/W-0h							

表 8-79. pwm_bri14 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS14_OR_16-bits_PWM_lower_8_bits_7:0_for_CS7	R/W	0h	8-bits PWM for CS14 OR 16-bits PWM lower 8 bits [7:0] for CS7

8.6.8.16 pwm_bri15 Register (Address = 20Fh) [Default = 0h]

pwm_bri15 is shown in [图 8-80](#) and described in [表 8-80](#).

Return to the [Summary Table](#).

图 8-80. pwm_bri15 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS15_OR_16-bits_PWM_higher_8_bits_15:8_for_CS7							
R/W-0h							

表 8-80. pwm_bri15 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS15_OR_16-bits_PWM_higher_8_bits_15:8_for_CS7	R/W	0h	8-bits PWM for CS15 OR 16-bits PWM higher 8 bits [15:8] for CS7

8.6.8.17 pwm_bri16 Register (Address = 210h) [Default = 0h]

pwm_bri16 is shown in [图 8-81](#) and described in [表 8-81](#).

Return to the [Summary Table](#).

图 8-81. pwm_bri16 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS16_OR_16-bits_PWM_lower_8_bits_7:0_for_CS8							
R/W-0h							

表 8-81. pwm_bri16 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS16_OR_16-bits_PWM_lower_8_bits_7:0_for_CS8	R/W	0h	8-bits PWM for CS16 OR 16-bits PWM lower 8 bits [7:0] for CS8

8.6.8.18 pwm_bri17 Register (Address = 211h) [Default = 0h]

pwm_bri17 is shown in [图 8-82](#) and described in [表 8-82](#).

Return to the [Summary Table](#).

图 8-82. pwm_bri17 Register

7	6	5	4	3	2	1	0
8-bits_PWM_for_CS17_OR_16-bits_PWM_higher_8_bits_15:8_for_CS8							
R/W-0h							

表 8-82. pwm_bri17 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	8-bits_PWM_for_CS17_OR_16-bits_PWM_higher_8_bits_15:8_for_CS8	R/W	0h	8-bits PWM for CS17 OR 16-bits PWM higher 8 bits [15:8] for CS8

8.6.8.19 pwm_bri18 Register (Address = 212h) [Default = 0h]

pwm_bri18 is shown in [图 8-83](#) and described in [表 8-83](#).

Return to the [Summary Table](#).

图 8-83. pwm_bri18 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS9							
R/W-0h							

表 8-83. pwm_bri18 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS9	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS9

8.6.8.20 pwm_bri19 Register (Address = 213h) [Default = 0h]

pwm_bri19 is shown in [图 8-84](#) and described in [表 8-84](#).

Return to the [Summary Table](#).

图 8-84. pwm_bri19 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS9							
R/W-0h							

表 8-84. pwm_bri19 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS9	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS9

8.6.8.21 pwm_bri20 Register (Address = 214h) [Default = 0h]

pwm_bri20 is shown in [图 8-85](#) and described in [表 8-85](#).

Return to the [Summary Table](#).

图 8-85. pwm_bri20 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS10							
R/W-0h							

表 8-85. pwm_bri20 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS10	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS10

8.6.8.22 pwm_bri21 Register (Address = 215h) [Default = 0h]

pwm_bri21 is shown in [图 8-86](#) and described in [表 8-86](#).

[Return to the Summary Table.](#)

图 8-86. pwm_bri21 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS10							
R/W-0h							

表 8-86. pwm_bri21 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS10	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS10

8.6.8.23 pwm_bri22 Register (Address = 216h) [Default = 0h]

pwm_bri22 is shown in [图 8-87](#) and described in [表 8-87](#).

[Return to the Summary Table.](#)

图 8-87. pwm_bri22 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS11							
R/W-0h							

表 8-87. pwm_bri22 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS11	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS11

8.6.8.24 pwm_bri23 Register (Address = 217h) [Default = 0h]

pwm_bri23 is shown in [图 8-88](#) and described in [表 8-88](#).

[Return to the Summary Table.](#)

图 8-88. pwm_bri23 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS11							
R/W-0h							

表 8-88. pwm_bri23 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS11	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS11

8.6.8.25 pwm_bri24 Register (Address = 218h) [Default = 0h]

pwm_bri24 is shown in [图 8-89](#) and described in [表 8-89](#).

[Return to the Summary Table.](#)

图 8-89. pwm_bri24 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS12							
R/W-0h							

表 8-89. pwm_bri24 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS12	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS12

8.6.8.26 pwm_bri25 Register (Address = 219h) [Default = 0h]

pwm_bri25 is shown in [图 8-90](#) and described in [表 8-90](#).

Return to the [Summary Table](#).

图 8-90. pwm_bri25 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS12							
R/W-0h							

表 8-90. pwm_bri25 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS12	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS12

8.6.8.27 pwm_bri26 Register (Address = 21Ah) [Default = 0h]

pwm_bri26 is shown in [图 8-91](#) and described in [表 8-91](#).

Return to the [Summary Table](#).

图 8-91. pwm_bri26 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS13							
R/W-0h							

表 8-91. pwm_bri26 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS13	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS13

8.6.8.28 pwm_bri27 Register (Address = 21Bh) [Default = 0h]

pwm_bri27 is shown in [图 8-92](#) and described in [表 8-92](#).

Return to the [Summary Table](#).

图 8-92. pwm_bri27 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS13							

图 8-92. pwm_bri27 Register (continued)

R/W-0h

表 8-92. pwm_bri27 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS13	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS13

8.6.8.29 pwm_bri28 Register (Address = 21Ch) [Default = 0h]

 pwm_bri28 is shown in [图 8-93](#) and described in [表 8-93](#).

 Return to the [Summary Table](#).

图 8-93. pwm_bri28 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS14							
R/W-0h							

表 8-93. pwm_bri28 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS14	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS14

8.6.8.30 pwm_bri29 Register (Address = 21Dh) [Default = 0h]

 pwm_bri29 is shown in [图 8-94](#) and described in [表 8-94](#).

 Return to the [Summary Table](#).

图 8-94. pwm_bri29 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS14							
R/W-0h							

表 8-94. pwm_bri29 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS14	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS14

8.6.8.31 pwm_bri30 Register (Address = 21Eh) [Default = 0h]

 pwm_bri30 is shown in [图 8-95](#) and described in [表 8-95](#).

 Return to the [Summary Table](#).

图 8-95. pwm_bri30 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS15							
R/W-0h							

表 8-95. pwm_bri30 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS15	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS15

8.6.8.32 pwm_bri31 Register (Address = 21Fh) [Default = 0h]

pwm_bri31 is shown in [图 8-96](#) and described in [表 8-96](#).

Return to the [Summary Table](#).

图 8-96. pwm_bri31 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS15							
R/W-0h							

表 8-96. pwm_bri31 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS15	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS15

8.6.8.33 pwm_bri32 Register (Address = 220h) [Default = 0h]

pwm_bri32 is shown in [图 8-97](#) and described in [表 8-97](#).

Return to the [Summary Table](#).

图 8-97. pwm_bri32 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS16							
R/W-0h							

表 8-97. pwm_bri32 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS16	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS16

8.6.8.34 pwm_bri33 Register (Address = 221h) [Default = 0h]

pwm_bri33 is shown in [图 8-98](#) and described in [表 8-98](#).

Return to the [Summary Table](#).

图 8-98. pwm_bri33 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS16							
R/W-0h							

表 8-98. pwm_bri33 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS16	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS16

8.6.8.35 pwm_bri34 Register (Address = 222h) [Default = 0h]

 pwm_bri34 is shown in [图 8-99](#) and described in [表 8-99](#).

 Return to the [Summary Table](#).

图 8-99. pwm_bri34 Register

7	6	5	4	3	2	1	0
16-bits_PWM_lower_8_bits_7:0_for_CS17							
R/W-0h							

表 8-99. pwm_bri34 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_lower_8_bits_7:0_for_CS17	R/W	0h	16-bits PWM lower 8 bits [7:0] for CS17

8.6.8.36 pwm_bri35 Register (Address = 223h) [Default = 0h]

 pwm_bri35 is shown in [图 8-100](#) and described in [表 8-100](#).

 Return to the [Summary Table](#).

图 8-100. pwm_bri35 Register

7	6	5	4	3	2	1	0
16-bits_PWM_higher_8_bits_15:8_for_CS17							
R/W-0h							

表 8-100. pwm_bri35 Register Field Descriptions

Bit	Field	Type	Default	Description
7-0	16-bits_PWM_higher_8_bits_15:8_for_CS17	R/W	0h	16-bits PWM higher 8 bits [15:8] for CS17

9 Application and Implementation

备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The LP5861 integrates 18 constant current sinks, which can drive up to 18 LED dots or 6 RGB pixels and achieve great dimming effect. In smart home, gaming keyboards, and other human-machine interaction applications, the device can greatly improve user experience with a small amount of components.

9.2 Typical Application

9.2.1 Application

图 9-1 shows an example of typical application, which uses one LP5861 to drive 6 common-anode RGB LEDs through I²C communication.

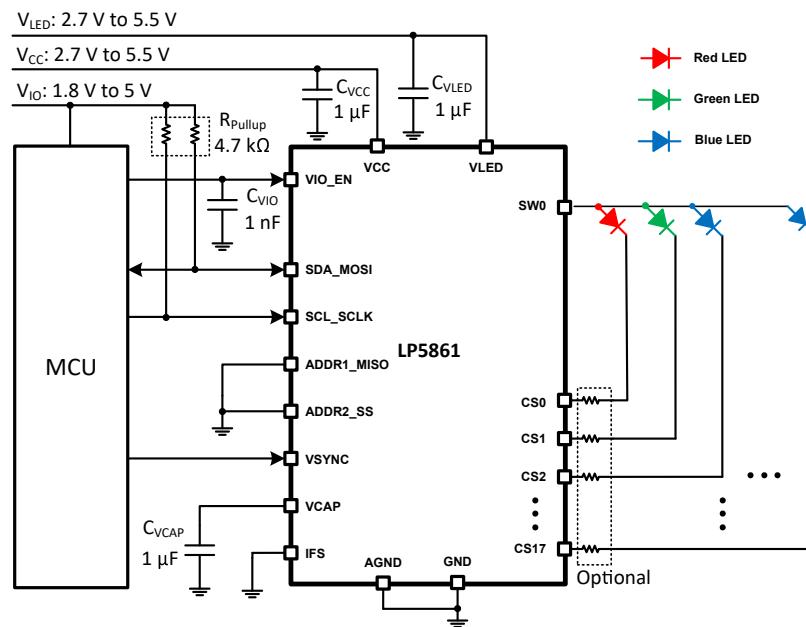


图 9-1. Typical Application - LP5861 Driving 6 RGB LEDs

Figure 9-2 shows an example of using LP5861 without internal power switch, to save power consumption on the internal PMOS, by connecting anode of LEDs to VLED directly. VLED still must be connected to 2.7 V - 5.5-V power supply, while SW0 must be floating when not used.

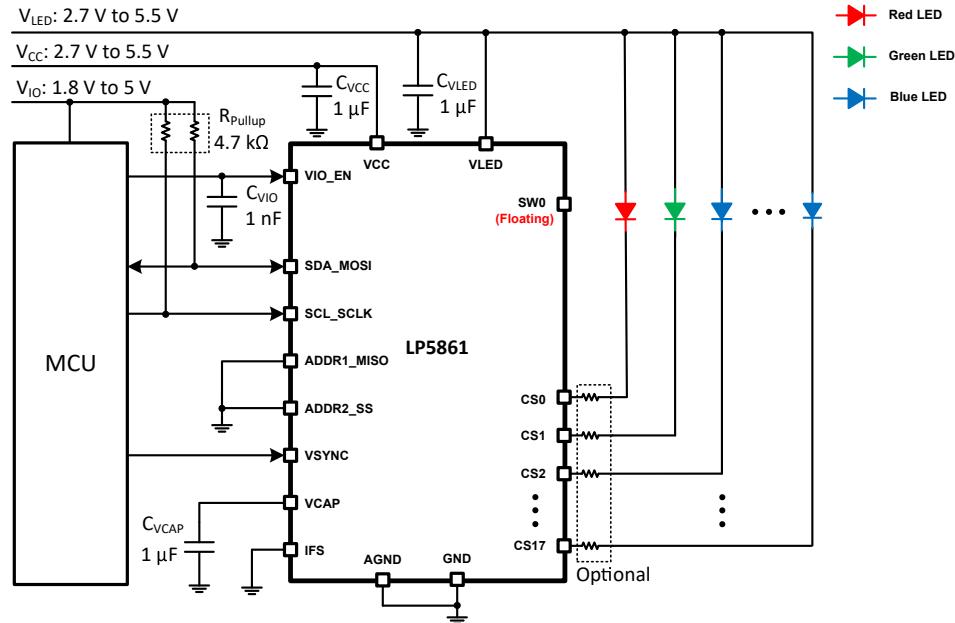


图 9-2. Typical Application 2 – LP5861 Drives Six RGB LEDs Without Internal Switch

9.2.2 Design Requirements

表 9-1. Design Parameters

PARAMETER	VALUE
VCC / VIO	3.3 V
VLED	5 V
RGB LED count	6
Interface	I ² C
LED maximum peak current (red, green, blue)	44 mA, 33 mA, 22 mA

9.2.3 Detailed Design Procedure

LP5861 requires an external capacitor C_{VCAP} , whose value is $1 \mu F$ connected from V_{CAP} to GND for proper operation of internal LDO. The external capacitor must be placed as close to the device as possible.

TI recommends $1-\mu F$ capacitors to be placed between VCC / VLED with GND, and $1-nF$ capacitor placed between VIO with GND. Place the capacitors as close to the device as possible.

Pullup resistors $R_{pull-up}$ are requirement for SCL and SDA when using I²C as communication method. In typical applications, TI recommends $1.8-k\Omega$ to $4.7-k\Omega$ resistors.

To decrease thermal dissipation from device to ambient, resistors R_{CS} an optionally be placed in serial with the LED. Voltage drop on these resistors must leave enough margins for VSAT to ensure the device work normally.

9.2.4 Program Procedure

When selecting data refresh Mode 1, outputs are refreshed instantly after data is received.

When selecting data refresh Mode 2 and 3, VSYNC signal is required for synchronized display. Programming flow is showed as 图 9-3. To display full pixel of last frame, VSYNC pulse must be sent to the device after the end of last PWM. Time between two pulses t_{SYNC} must be larger than the whole PWM time of all Dots t_{frame} . Common selection like 60 Hz, 90 Hz, 120 Hz or even higher refresh frequency can be supported. High pulse width longer than t_{SYNC_H} is required at the beginning of each VSYNC frame, and data must not be write to PWM registers during high pulse width.

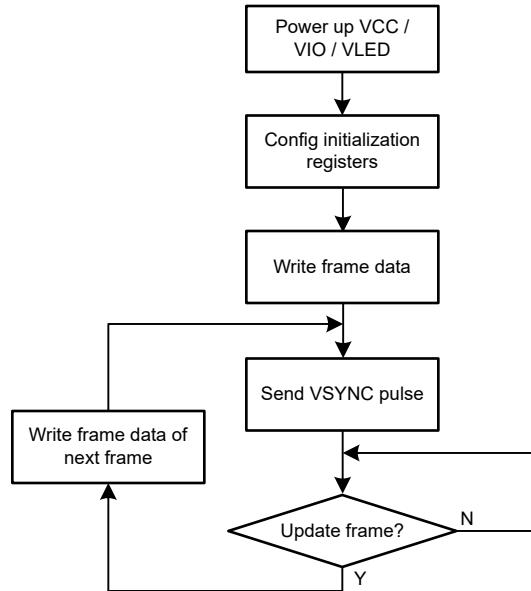
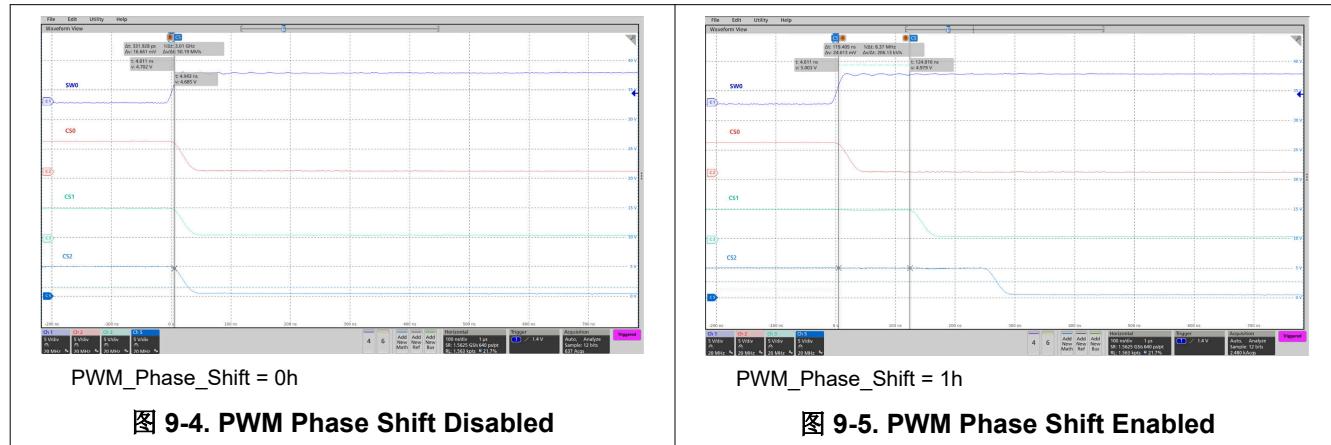


图 9-3. Program Procedure

9.2.5 Application Performance Plots

The following figures show the application performance plots.



10 Power Supply Recommendations

VDD Input Supply Recommendations

LP5861 is designed to operate from a 2.7-V to 5.5-V VDD voltage supply. This input supply must be well regulated and be able to provide the peak current required by the LED matrix. The resistance of the VDD supply rail must be low enough such that the input current transient does not cause the LP5861 VDD supply voltage to drop below the maximum POR voltage.

VLED Input Supply Recommendations

LP5861 is designed to operate with a 2.7-V to 5.5-V VLED voltage supply. The VLED supply must be well regulated and able to provide the peak current required by the LED configuration without voltage drop, under load transients like start-up or rapid brightness change. The resistance of the input supply rail must be low enough so that the input current transient does not cause the VLED supply voltage to drop below LED $V_f + VSAT$ voltage.

VIO Input Supply Recommendations

LP5861 is designed to operate with a 1.65-V to 5.5-V VIO_EN voltage supply. The VIO_EN supply must be well regulated and able to provide the peak current required by the LED configuration without voltage drop under load transients like start-up or rapid brightness change.

11 Layout

11.1 Layout Guidelines

The below guidelines for layout design can help to get a better on-board performance.

- The decoupling capacitors C_{VCC} and C_{VLED} for power supply must be close to the chip to have minimized the impact of high-frequency noise and ripple from power. C_{VCAP} for internal LDO must be put as close to chip as possible. GND plane connections to C_{VLED} and GND pins must be on TOP layer copper with multiple vias connecting to system ground plane. C_{VIO} for internal enable block also must be put as close to chip as possible.
- The exposed thermal pad must be well soldered to the board, which can have better mechanical reliability. This action can optimize heat transfer so that increasing thermal performance. AGND pin must be connected to thermal pad and system ground.
- The major heat flow path from the package to the ambient is through copper on the PCB. Several methods can help thermal performance. Below exposed thermal pad of IC, putting much vias through the PCB to other ground layer can dissipate more heat. Maximizing the copper coverage on the PCB can increase the thermal conductivity of the board.
- Low inductive and resistive path of switch load loop can help to provide a high slew rate. Therefore, path of VLED – SWx must be short and wide and avoid parallel wiring and narrow trace. Transient current in SWx pins is much larger than CSy pins, so that trace for SWx must be wider than CSy.

11.2 Layout Example

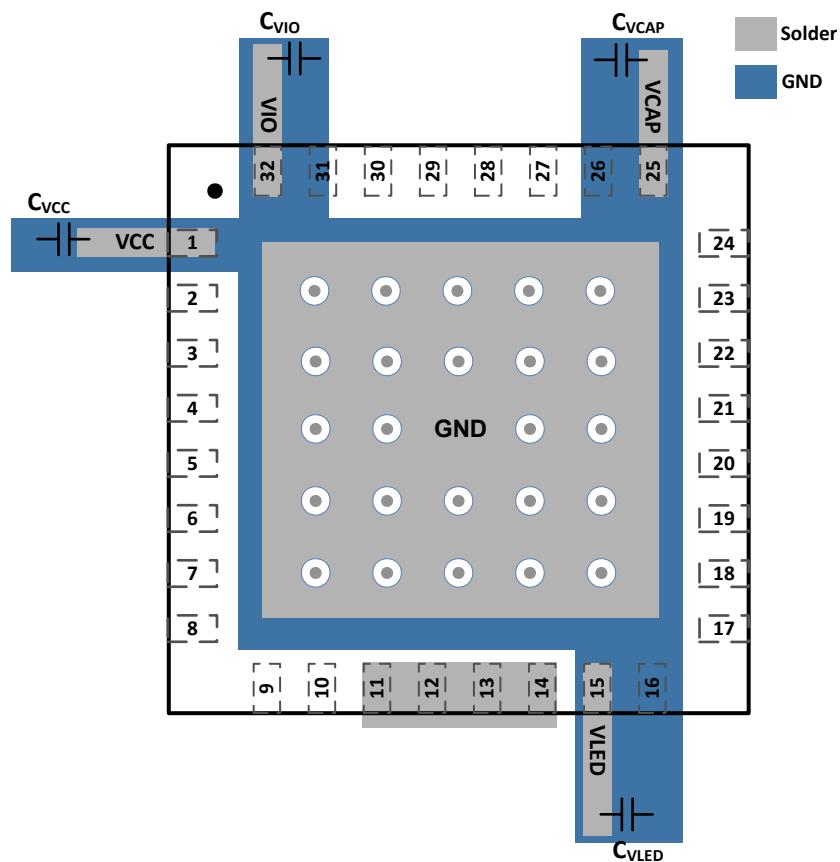


图 11-1. LP5861 Layout Example

12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

12.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.2 支持资源

[TI E2E™ 支持论坛](#)是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

12.3 Trademarks

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12.4 Electrostatic Discharge Caution

 This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 术语表

TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LP5861RSMR	Active	Production	VQFN (RSM) 32	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5861
LP5861RSMR.A	Active	Production	VQFN (RSM) 32	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5861

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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GENERIC PACKAGE VIEW

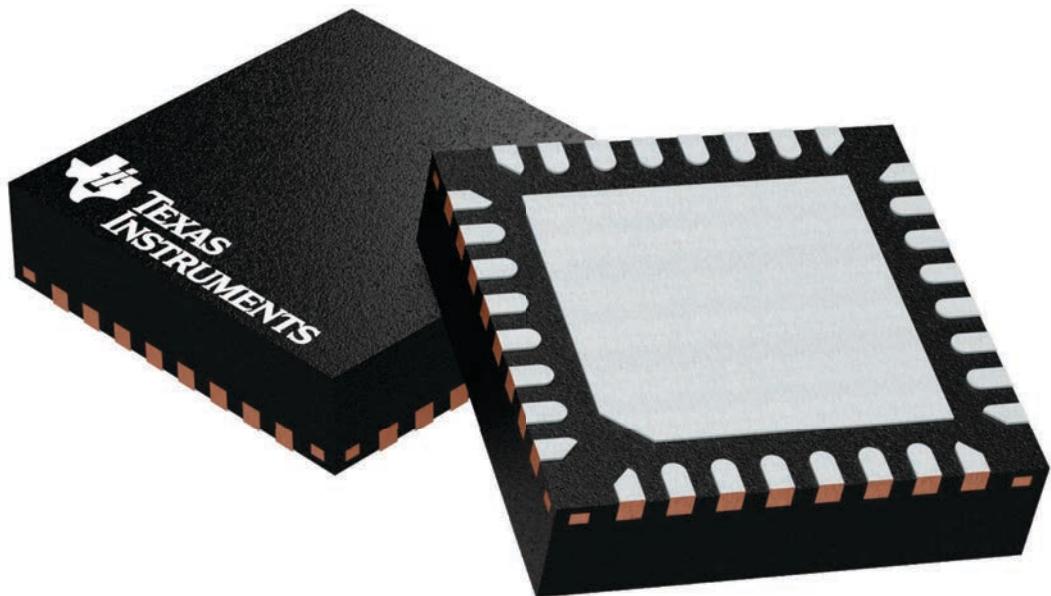
RSM 32

VQFN - 1 mm max height

4 x 4, 0.4 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

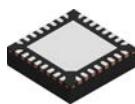
This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224982/A

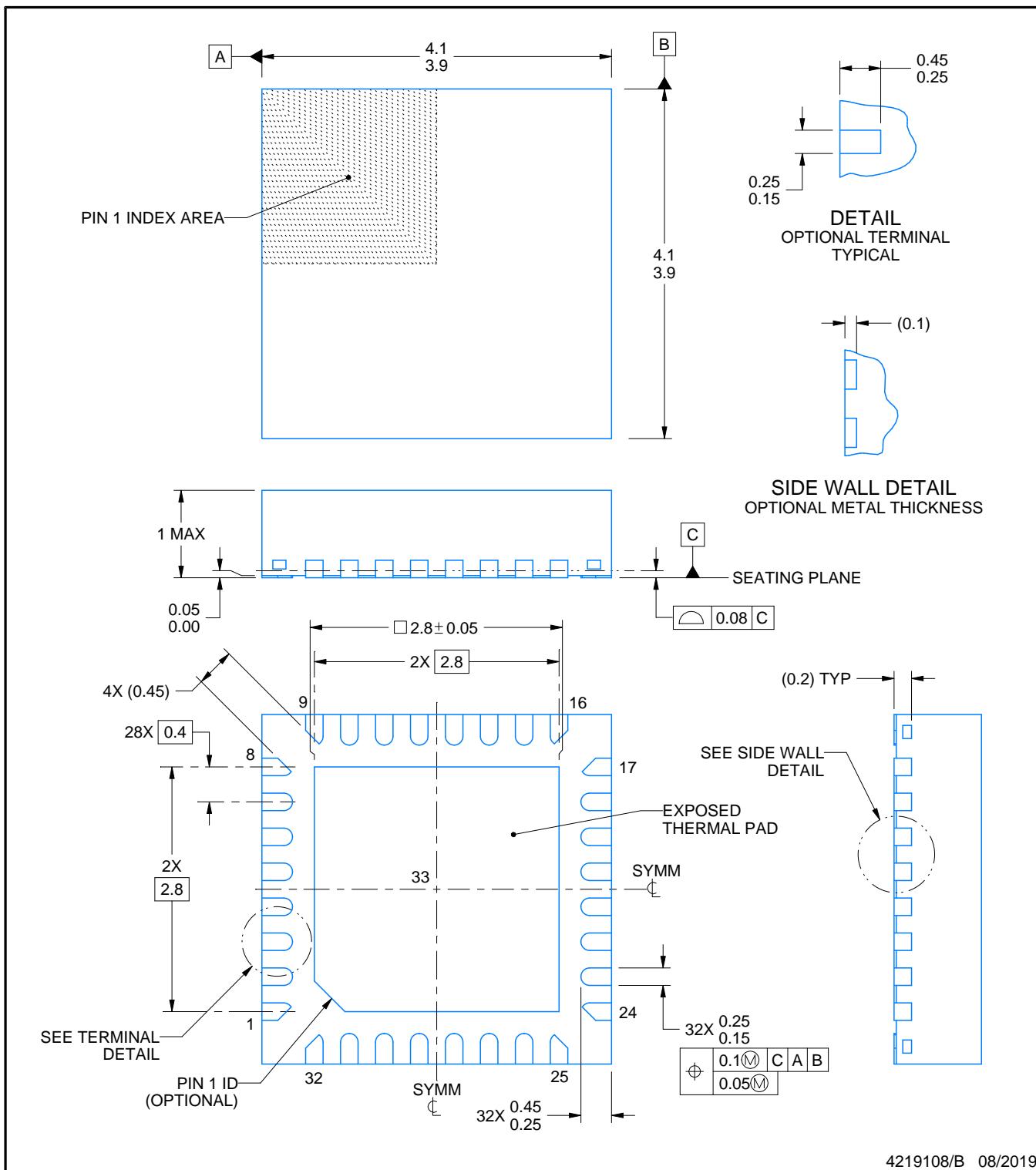
PACKAGE OUTLINE

RSM0032B



VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4219108/B 08/2019

NOTES:

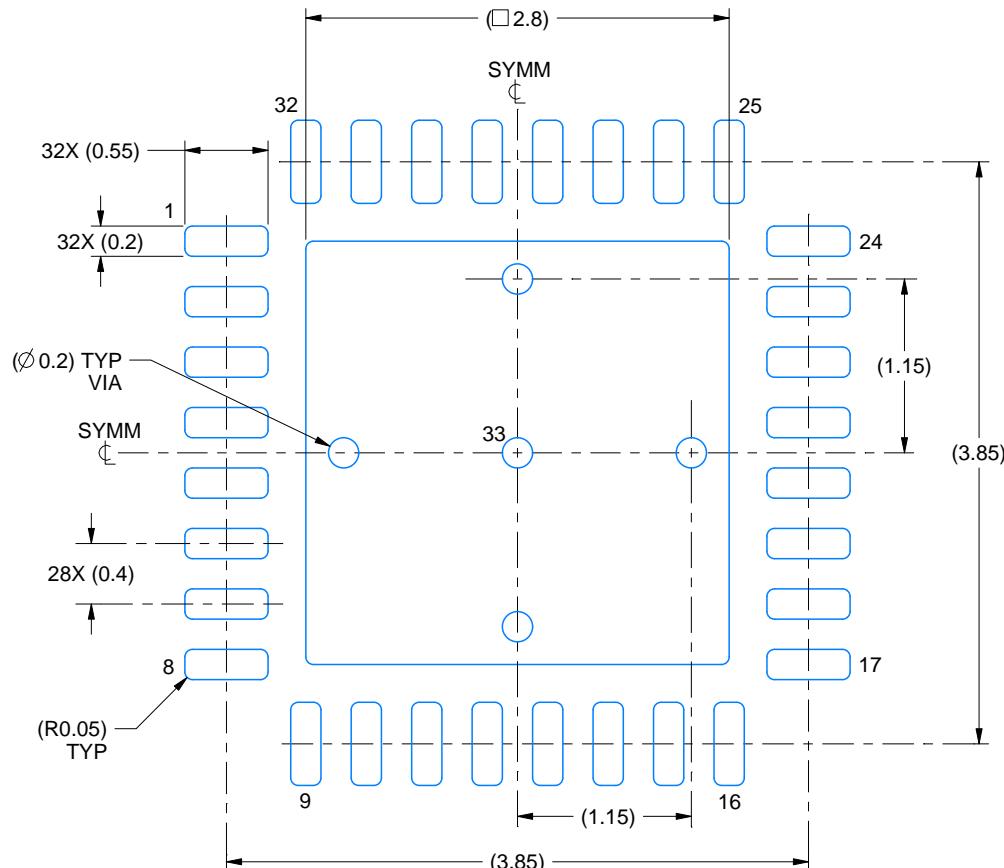
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

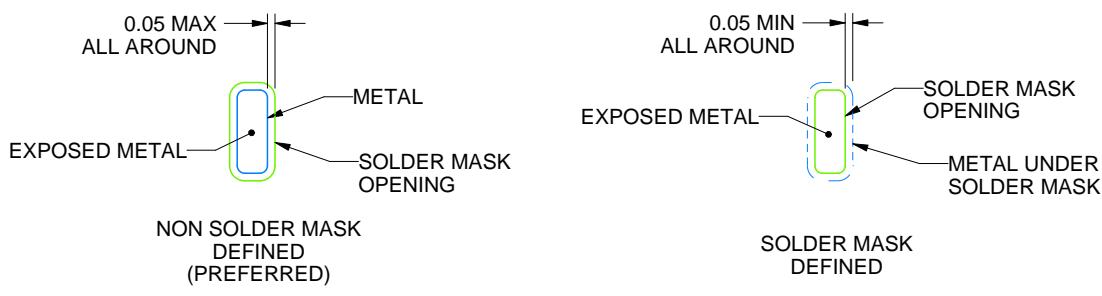
RSM0032B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4219108/B 08/2019

NOTES: (continued)

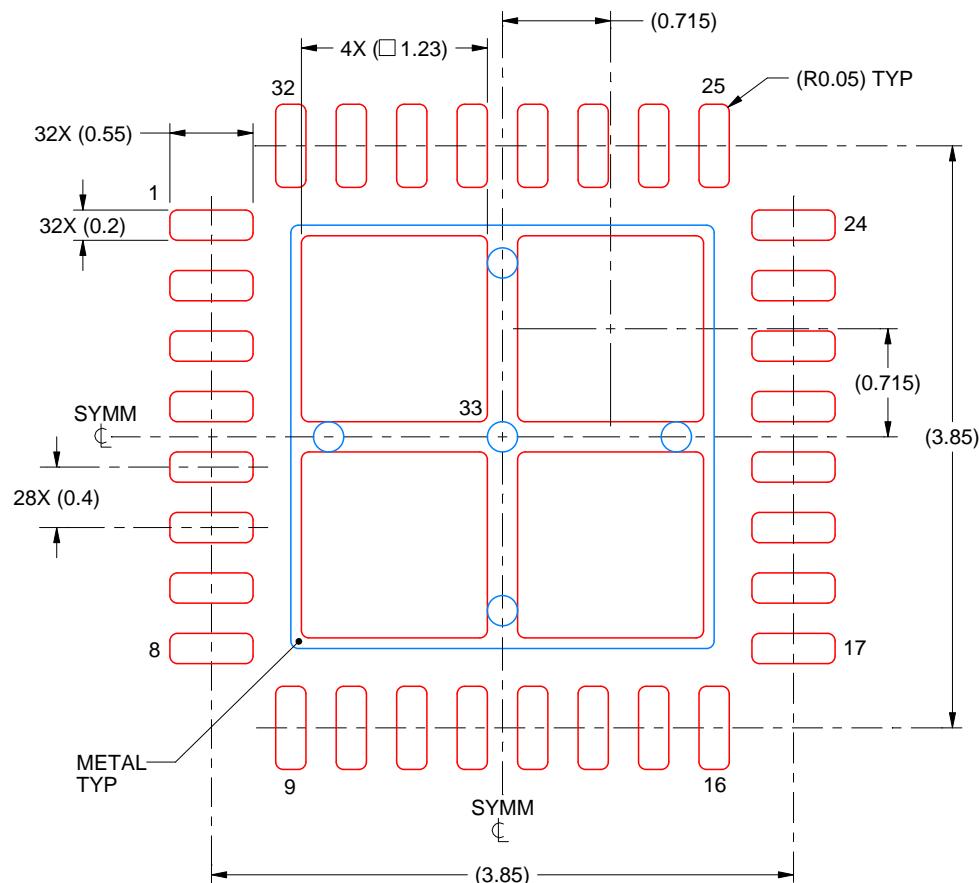
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RSM0032B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL

EXPOSED PAD 33:
77% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:20X

4219108/B 08/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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